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April 1<sup>st</sup>, 2010 Renesas Electronics Corporation

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# RENESAS

R8C/26 Group, R8C/27 Group SINGLE-CHIP 16-BIT CMOS MCU

# 1. Overview

These MCUs are fabricated using a high-performance silicon gate CMOS process, embedding the R8C CPU core, and are packaged in a 32-pin molded-plastic LQFP. It implements sophisticated instructions for a high level of instruction efficiency. With 1 Mbyte of address space, they are capable of executing instructions at high speed. Furthermore, the R8C/27 Group has on-chip data flash (1 KB  $\times$  2 blocks).

The difference between the R8C/26 Group and R8C/27 Group is only the presence or absence of data flash. Their peripheral functions are the same.

# 1.1 Applications

Electronic household appliances, office equipment, audio equipment, consumer products, automotive, etc.



#### **1.2 Performance Overview**

Table 1.1 outlines the Functions and Specifications for R8C/26 Group and Table 1.2 outlines the Functions and Specifications for R8C/27 Group.

	Item	Specification
CPU	Number of	89 instructions
	fundamental	
	instructions Minimum instruction	50 ns (f(XIN) = 20 MHz, VCC = 3.0 to 5.5 V) (other than K version)
	Minimum instruction	62.5  ns (f(XIN) = 20  MHz,  VCC = 3.0  to  5.5  V) (other than K version) (62.5  ns (f(XIN) = 16  MHz,  VCC = 3.0  to  5.5  V) (K  version)
	execution time	100  ns (f(XIN) = 10  MHz, VCC = 3.0 to 5.5 V) (K Version) 100 ns (f(XIN) = 10 MHz, VCC = 2.7 to 5.5 V)
		200 ns (f(XIN) = 5 MHz, VCC = 2.2 to 5.5 V) (N, D version)
	Operating mode	Single-chip
	Address space	1 Mbyte
	Memory capacity	Refer to Table 1.3 Product Information for R8C/26 Group
Peripheral	Ports	I/O ports: 25 pins, Input port: 3 pins
Functions	LED drive ports	I/O ports: 8 pins (N, D version)
	Timers	Timer RA: 8 bits × 1 channel
		Timer RB: 8 bits × 1 channel
		(Each timer equipped with 8-bit prescaler)
		Timer RC: 16 bits × 1 channel
		(Input capture and output compare circuits)
		Timer RE: With real-time clock and compare match function
		(For J, K version, compare match function only.)
	Serial interfaces	2 channels (UART0, UART1)
		Clock synchronous serial I/O, UART
	Clock synchronous	1 channel
	serial interface	I <sup>2</sup> C bus Interface <sup>(1)</sup>
		Clock synchronous serial I/O with chip select
	LIN module	Hardware LIN: 1 channel (timer RA, UART0)
	A/D converter	
		10-bit A/D converter: 1 circuit, 12 channels
	Watchdog timer	15 bits × 1 channel (with prescaler)
		Start-on-reset selectable
	Interrupts	Internal: 15 sources, External: 4 sources,
		Software: 4 sources, Priority levels: 7 levels
	Clock generation	3 circuits
	circuits	<ul> <li>XIN clock generation circuit (with on-chip feedback resistor)</li> </ul>
		On-chip oscillator (high speed, low speed)
		High-speed on-chip oscillator has a frequency adjustment function
		<ul> <li>XCIN clock generation circuit (32 kHz) (N, D version)</li> </ul>
		<ul> <li>Real-time clock (timer RE) (N, D version)</li> </ul>
	Oscillation-stopped	XIN clock oscillation stop detection function
	detector	
	Voltage detection	On-chip
	circuit	
	Power-on reset circuit	On-chip
Electrical	Supply voltage	VCC = 3.0 to 5.5 V (f(XIN) = 20 MHz) (other than K version)
Characteristics		VCC = 3.0  to  5.5  V (f(XIN) = 16  MHz) (K  version)
2		VCC = 2.7 to 5.5 V (f(XIN) = 10 MHz)
		VCC = 2.2 to 5.5 V (f(XIN) = 5 MHz) (N, D version)
	Current consumption	Typ. 10 mA (VCC = $5.0 \text{ V}$ , f(XIN) = $20 \text{ MHz}$ )
	(N, D version)	Typ. 6 mA (VCC = $3.0 \text{ V}$ , f(XIN) = $10 \text{ MHz}$ )
		Typ. 2.0 $\mu$ A (VCC = 3.0 V, wait mode (f(XCIN) = 32 kHz)
		Typ. 0.7 $\mu$ A (VCC = 3.0 V, stop mode)
	Programming and	VCC = 2.7  to  5.5  V
	erasure voltage	
Flash Memory		
Flash Memory		100 time an
Flash Memory	Programming and	100 times
	Programming and erasure endurance	
	Programming and erasure endurance	-20 to 85°C (N version)
Operating Ambie	Programming and erasure endurance	

 Table 1.1
 Functions and Specifications for R8C/26 Group

NOTES:

1. I<sup>2</sup>C bus is a trademark of Koninklijke Philips Electronics N. V.

2. Specify the D, K version if D, K version functions are to be used.

CPU	Item Number of fundamental	Specification 89 instructions
CPU		
	instructions	
	Minimum instruction	50 ns (f(XIN) = 20 MHz, VCC = 3.0 to 5.5 V) (other than K version) (25  so (f(XIN)) = 40  MHz + 100  so = 2.0  to  5.5  V) (f(x)  sortion)
	execution time	62.5 ns (f(XIN) = 16 MHz, VCC = 3.0 to 5.5 V) (K version)
		100 ns (f(XIN) = 10 MHz, VCC = 2.7 to 5.5 V) 200 ns (f(XIN) = 5 MHz, VCC = 2.3 to 5.5 V) (NL D version)
	Operating mode	200 ns (f(XIN) = 5 MHz, VCC = 2.2 to 5.5 V) (N, D version)
	Operating mode	Single-chip
	Address space	1 Mbyte
Daniah anal	Memory capacity	Refer to Table 1.4 Product Information of R8C/27 Group
Peripheral	Ports	I/O ports: 25 pins, Input port: 3 pins
Functions	LED drive ports	I/O ports: 8 pins (N, D version)
	Timers	Timer RA: 8 bits × 1 channel
		Timer RB: 8 bits × 1 channel
		(Each timer equipped with 8-bit prescaler)
		Timer RC: 16 bits × 1 channel
		(Input capture and output compare circuits)
		Timer RE: With real-time clock and compare match function
	O a ni a l in ta nf	(For J, K version, compare match function only.)
	Serial interfaces	2 channels (UART0, UART1)
		Clock synchronous serial I/O, UART
	Clock synchronous	1 channel
	serial interface	I <sup>2</sup> C bus Interface <sup>(1)</sup>
		Clock synchronous serial I/O with chip select
	LIN module	Hardware LIN: 1 channel (timer RA, UART0)
	A/D converter	10-bit A/D converter: 1 circuit, 12 channels
	Watchdog timer	15 bits x 1 channel (with prescaler)
		Start-on-reset selectable
	Interrupts	Internal: 15 sources, External: 4 sources,
		Software: 4 sources, Priority levels: 7 levels
	Clock generation	3 circuits
	circuits	<ul> <li>XIN clock generation circuit (with on-chip feedback resistor)</li> </ul>
		<ul> <li>On-chip oscillator (high speed, low speed)</li> </ul>
		High-speed on-chip oscillator has a frequency adjustment function
		<ul> <li>XCIN clock generation circuit (32 kHz) (N, D version)</li> </ul>
		Real-time clock (timer RE) (N, D version)
	Oscillation-stopped	XIN clock oscillation stop detection function
	detector	2
	Voltage detection circuit	On-chip
	Power-on reset circuit	On-chip
Electrical	Supply voltage	VCC = $3.0$ to $5.5$ V (f(XIN) = $20$ MHz) (other than K version)
Characteristics		VCC = $3.0 \text{ to } 5.5 \text{ V} (f(XIN) = 16 \text{ MHz}) (K \text{ version})$
		VCC = 2.7 to 5.5 V ( $f(XIN) = 10 \text{ MHz}$ )
	-	VCC = 2.2 to 5.5 V (f(XIN) = 5 MHz) (N, D version)
	Current consumption	Typ. 10 mA (VCC = 5.0 V, f(XIN) = 20 MHz)
	(N, D version)	Typ. 6 mA (VCC = 3.0 V, f(XIN) = 10 MHz)
		Typ. 2.0 $\mu$ A (VCC = 3.0 V, wait mode (f(XCIN) = 32 kHz)
		Typ. 0.7 μA (VCC = 3.0 V, stop mode)
Flash Memory	Programming and	VCC = 2.7 to 5.5 V
	erasure voltage	
	Programming and	10,000 times (data flash)
	erasure endurance	1,000 times (program ROM)
Operating Ambie	ent Temperature	-20 to 85°C (N version)
		-40 to 85°C (D, J version) <sup>(2)</sup> , -40 to 125°C (K version) <sup>(2)</sup>
Package		32-pin molded-plastic LQFP

1. I<sup>2</sup>C bus is a trademark of Koninklijke Philips Electronics N. V.

2. Specify the D, K version if D, K version functions are to be used.

#### 1.3 **Block Diagram**

Figure 1.1 shows a Block Diagram.



Figure 1.1 **Block Diagram** 



#### 1.4 **Product Information**

Table 1.3 lists the Product Information for R8C/26 Group and Table 1.4 lists the Product Information for R8C/27 Group.

Part No.ROM CapacityRAM CapacityPackage TypeRemarkR5F21262SNFP8 Kbytes512 bytesPLQP0032GB-AN versionR5F21264SNFP16 Kbytes1 KbytePLQP0032GB-AN versionR5F21265SNFP24 Kbytes1.5 KbytesPLQP0032GB-AN versionR5F21266SNFP32 Kbytes1.5 KbytesPLQP0032GB-AD versionR5F21264SDFP8 Kbytes512 bytesPLQP0032GB-AD versionR5F21264SDFP16 Kbytes1 KbytePLQP0032GB-AD versionR5F21266SDFP24 Kbytes1.5 KbytesPLQP0032GB-AD versionR5F21266SDFP32 Kbytes1.5 KbytesPLQP0032GB-AD versionR5F21264JFP16 Kbytes1 KbytePLQP0032GB-AJ versionR5F21264JFP32 Kbytes1.5 KbytesPLQP0032GB-AJ versionR5F21264JFP16 Kbytes1 KbytePLQP0032GB-AJ versionR5F21264JFP16 Kbytes1 KbytePLQP0032GB-AK version			
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R5F21266JFP 32 Kbytes 1.5 Kbytes PLQP0032GB-A			
R5F21264KFP 16 Kbytes 1 Kbyte PLOP0032GB-A K version			
R5F21266KFP 32 Kbytes 1.5 Kbytes PLQP0032GB-A			
R5F21262SNXXXFP 8 Kbytes 512 bytes PLQP0032GB-A N version Fac	ctory		
R5F21264SNXXXFP 16 Kbytes 1 Kbyte PLQP0032GB-A prog	gramming		
R5F21265SNXXXFP 24 Kbytes 1.5 Kbytes PLQP0032GB-A prod	duct <sup>(1)</sup>		
R5F21266SNXXXFP 32 Kbytes 1.5 Kbytes PLQP0032GB-A			
R5F21262SDXXXFP 8 Kbytes 512 bytes PLQP0032GB-A D version			
R5F21264SDXXXFP 16 Kbytes 1 Kbyte PLQP0032GB-A			
R5F21265SDXXXFP 24 Kbytes 1.5 Kbytes PLQP0032GB-A			
R5F21266SDXXXFP 32 Kbytes 1.5 Kbytes PLQP0032GB-A			
R5F21264JXXXFP 16 Kbytes 1 Kbyte PLQP0032GB-A J version			
R5F21266JXXXFP 32 Kbytes 1.5 Kbytes PLQP0032GB-A			
R5F21264KXXXFP 16 Kbytes 1 Kbyte PLQP0032GB-A K version			
R5F21266KXXXFP 32 Kbytes 1.5 Kbytes PLQP0032GB-A			

#### **Product Information for R8C/26 Group** Table 1.3

NOTE:

1. The user ROM is programmed before shipment.





Figure 1.2 Part Number, Memory Size, and Package of R8C/26 Group



1.	Overview

ROM	Capacity	DAM			
Program ROM	Data flash	Capacity	Package Type	Re	marks
8 Kbytes	1 Kbyte x 2	512 bytes	PLQP0032GB-A	N version	
16 Kbytes	1 Kbyte x 2	1 Kbyte	PLQP0032GB-A		
24 Kbytes	1 Kbyte x 2	1.5 Kbytes	PLQP0032GB-A		
32 Kbytes	1 Kbyte x 2	1.5 Kbytes	PLQP0032GB-A		
8 Kbytes	1 Kbyte x 2	512 bytes	PLQP0032GB-A	D version	
16 Kbytes	1 Kbyte x 2	1 Kbyte	PLQP0032GB-A		
24 Kbytes	1 Kbyte x 2	1.5 Kbytes	PLQP0032GB-A		
32 Kbytes	1 Kbyte x 2	1.5 Kbytes	PLQP0032GB-A		
16 Kbytes	1 Kbyte x 2	1 Kbyte	PLQP0032GB-A	J version	
32 Kbytes	1 Kbyte x 2	1.5 Kbytes	PLQP0032GB-A		
16 Kbytes	1 Kbyte x 2	1 Kbyte	PLQP0032GB-A	K version	
32 Kbytes	1 Kbyte x 2	1.5 Kbytes	PLQP0032GB-A		
8 Kbytes	1 Kbyte x 2	512 bytes	PLQP0032GB-A	N version	Factory
16 Kbytes	1 Kbyte x 2	1 Kbyte	PLQP0032GB-A		programming
24 Kbytes	1 Kbyte x 2	1.5 Kbytes	PLQP0032GB-A		product <sup>(1)</sup>
32 Kbytes	1 Kbyte x 2	1.5 Kbytes	PLQP0032GB-A		
8 Kbytes	1 Kbyte x 2	512 bytes	PLQP0032GB-A	D version	
16 Kbytes	1 Kbyte x 2	1 Kbyte	PLQP0032GB-A		
24 Kbytes	1 Kbyte x 2	1.5 Kbytes	PLQP0032GB-A		
32 Kbytes	1 Kbyte x 2	1.5 Kbytes	PLQP0032GB-A		
16 Kbytes	1 Kbyte x 2	1 Kbyte	PLQP0032GB-A	J version	
32 Kbytes	1 Kbyte x 2	1.5 Kbytes	PLQP0032GB-A		
16 Kbytes	1 Kbyte x 2	1 Kbyte	PLQP0032GB-A	K version	
32 Kbytes	1 Kbyte x 2	1.5 Kbytes	PLQP0032GB-A		
	Program ROM 8 Kbytes 16 Kbytes 32 Kbytes	ROMData flash8 Kbytes1 Kbyte × 216 Kbytes1 Kbyte × 224 Kbytes1 Kbyte × 232 Kbytes1 Kbyte × 232 Kbytes1 Kbyte × 216 Kbytes1 Kbyte × 224 Kbytes1 Kbyte × 224 Kbytes1 Kbyte × 232 Kbytes1 Kbyte × 2	Program ROMData flashRAM Capacity8 Kbytes1 Kbyte × 2512 bytes16 Kbytes1 Kbyte × 21 Kbyte24 Kbytes1 Kbyte × 21.5 Kbytes32 Kbytes1 Kbyte × 21.5 Kbytes32 Kbytes1 Kbyte × 2512 bytes16 Kbytes1 Kbyte × 2512 bytes16 Kbytes1 Kbyte × 21.5 Kbytes32 Kbytes1 Kbyte × 21.5 Kbytes32 Kbytes1 Kbyte × 21.5 Kbytes32 Kbytes1 Kbyte × 21.5 Kbytes16 Kbytes1 Kbyte × 21.5 Kbytes32 Kbytes1 Kbyte × 21.5 Kbyt	Program ROMData flashRAM CapacityPackage Type8 Kbytes1 Kbyte × 2512 bytesPLQP0032GB-A16 Kbytes1 Kbyte × 21 KbytePLQP0032GB-A24 Kbytes1 Kbyte × 21.5 KbytesPLQP0032GB-A32 Kbytes1 Kbyte × 21.5 KbytesPLQP0032GB-A32 Kbytes1 Kbyte × 21.5 KbytesPLQP0032GB-A16 Kbytes1 Kbyte × 2512 bytesPLQP0032GB-A24 Kbytes1 Kbyte × 21.5 KbytesPLQP0032GB-A16 Kbytes1 Kbyte × 21.5 KbytesPLQP0032GB-A24 Kbytes1 Kbyte × 21.5 KbytesPLQP0032GB-A32 Kbytes1 Kbyt	Program ROMData flashRAM CapacityPackage TypeRe8 Kbytes1 Kbyte × 2512 bytesPLQP0032GB-AN version16 Kbytes1 Kbyte × 21 KbytePLQP0032GB-AN version24 Kbytes1 Kbyte × 21.5 KbytesPLQP0032GB-AD version32 Kbytes1 Kbyte × 21.5 KbytesPLQP0032GB-AD version16 Kbytes1 Kbyte × 2512 bytesPLQP0032GB-AD version16 Kbytes1 Kbyte × 21.5 KbytesPLQP0032GB-AD version16 Kbytes1 Kbyte × 21.5 KbytesPLQP0032GB-AD version16 Kbytes1 Kbyte × 21.5 KbytesPLQP0032GB-AJ version32 Kbytes1 Kbyte × 21.5 KbytesPLQP0032GB-AJ version32 Kbytes1 Kbyte × 21.5 KbytesPLQP0032GB-AJ version32 Kbytes1 Kbyte × 21.5 KbytesPLQP0032GB-AK version32 Kbytes1 Kbyte × 21.5 KbytesPLQP0032GB-AK version32 Kbytes1 Kbyte × 21.5 KbytesPLQP0032GB-AN version16 Kbytes1 Kbyte × 21.5 KbytesPLQP0032GB-AD version16 Kbytes1 Kbyte × 2 <td< td=""></td<>

 Table 1.4
 Product Information for R8C/27 Group

Current of Sep. 2008

NOTE:

1. The user ROM is programmed before shipment.



Figure 1.3 Part Number, Memory Size, and Package of R8C/27 Group



### 1.5 Pin Assignments

Figure 1.4 shows Pin Assignments (Top View).



Figure 1.4 Pin Assignments (Top View)

#### 1.6 Pin Functions

Table 1.5 lists Pin Functions.

#### Table 1.5Pin Functions

Туре	Symbol	I/O Type	Description
Power supply input	VCC, VSS	I	Apply 2.2 to 5.5 V (J, K version are 2.7 to 5.5 V) to the VCC pin. Apply 0 V to the VSS pin.
Analog power supply input	AVCC, AVSS	I	Power supply for the A/D converter. Connect a capacitor between AVCC and AVSS.
Reset input	RESET	I	Input "L" on this pin resets the MCU.
MODE	MODE	I	Connect this pin to VCC via a resistor.
XIN clock input	XIN	I	These pins are provided for XIN clock generation circuit I/O. Connect a ceramic resonator or a crystal oscillator between the XIN and XOUT pins. To use an external clock, input it to the
XIN clock output	XOUT	0	XIN pin and leave the XOUT pin open.
XCIN clock input (N, D version)	XCIN	I	These pins are provided for XCIN clock generation circuit I/O. Connect a crystal oscillator between the XCIN and XCOUT
XCIN clock output (N, D version)	XCOUT	0	pins. To use an external clock, input it to the XCIN pin and leave the XCOUT pin open.
INT interrupt input	INTO, INT1, INT3	I	INT interrupt input pins
Key input interrupt	KI0 to KI3	I	Key input interrupt input pins
Timer RA	TRAO	0	Timer RA output pin
	TRAIO	I/O	Timer RA I/O pin
Timer RB	TRBO	0	Timer RB output pin
Timer RC	TRCCLK	I	External clock input pin
	TRCTRG	I	External trigger input pin
	TRCIOA, TRCIOB, TRCIOC, TRCIOD	I/O	Sharing output-compare output / input-capture input / PWM / PWM2 output pins
Timer RE	TREO	0	Timer RE output pin
Serial interface	CLK0, CLK1	I/O	Clock I/O pin
	RXD0, RXD1	I	Receive data input pin
	TXD0, TXD1	0	Transmit data output pin
I <sup>2</sup> C bus interface	SCL	I/O	Clock I/O pin
	SDA	I/O	Data I/O pin
Clock synchronous	SSI	I/O	Data I/O pin
serial I/O with chip	SCS	I/O	Chip-select signal I/O pin
select	SSCK	I/O	Clock I/O pin
	SSO	I/O	Data I/O pin
Reference voltage input	VREF	I	Reference voltage input pin to A/D converter
A/D converter	AN0 to AN11	I	Analog input pins to A/D converter
I/O port	P0_0 to P0_7, P1_0 to P1_7, P3_1, P3_3 to P3_7, P4_5, P5_3, P5_4	I/O	CMOS I/O ports. Each port has an I/O select direction register, allowing each pin in the port to be directed for input or output individually. Any port set to input can be set to use a pull-up resistor or not by a program. P1_0 to P1_7 also function as LED drive ports (N, D version).
Input port	P4_2, P4_6, P4_7	I	Input-only ports

I: Input O: Output I/O: Input and output

				I/O Pin	Functions for a	of Peripheral Mo	dules	
Pin Number	Control Pin	Port	Interrupt	Timer	Serial Interface	Clock Synchronous Serial I/O with Chip Select	l <sup>2</sup> C bus Interface	A/D Converter
1		P3_5		(TRCIOD) <sup>(1)</sup>		SSCK	SCL	
2		P3_7		TRAO	RXD1/ (TXD1) <sup>(1, 3)</sup>	SSO		
3	RESET							
4	XOUT/XCOUT <sup>(2)</sup>	P4_7						
5	VSS/AVSS							
6	XIN/XCIN <sup>(2)</sup>	P4_6						
7	VCC/AVCC							
8	MODE							
9		P4_5	INT0		(RXD1) <sup>(1, 3)</sup>			
10		P1_7	INT1	TRAIO				
11		P3_6	(INT1) <sup>(1)</sup>		(TXD1)/ (RXD1) <sup>(1, 3)</sup>			
12		P3_1		TRBO				
13		P5_4		TRCIOD				
14		P5_3		TRCIOC				
15		P1_6			CLK0	(SSI) <sup>(1)</sup>		
16		P1_5	(INT1) <sup>(1)</sup>	(TRAIO) <sup>(1)</sup>	RXD0			
17		P1_4			TXD0			
18		P1_3	KI3	(TRBO)				AN11
19		P1_2	KI2	TRCIOB				AN10
20	VRFF	P4_2						
21		P1_1	KI1	TRCIOA/ TRCTRG				AN9
22		P1_0	KI0					AN8
23		P3_3	INT3	TRCCLK		SSI		
24		P3_4		(TRCIOC) <sup>(1)</sup>		SCS	SDA	
25		P0_7						AN0
26		P0_6						AN1
27		P0_5			CLK1			AN2
28		P0_4		TREO				AN3
29		P0_3						AN4
30		P0_2						AN5
31		P0_1						AN6
32		P0_0			(TXD1) <sup>(1, 3)</sup>			AN7

 Table 1.6
 Pin Name Information by Pin Number

1. This can be assigned to the pin in parentheses by a program.

2. XCIN, XCOUT can be used only for N or D version.

3. For the combination of using pins TXD1 and RXD1, refer to **Figure 15.7 Registers PINSR1 and PMR** of Hardware Manual (REJ09B0278).

# 2. Central Processing Unit (CPU)

Figure 2.1 shows the CPU Registers. The CPU contains 13 registers. R0, R1, R2, R3, A0, A1, and FB configure a register bank. There are two sets of register bank.



### 2.1 Data Registers (R0, R1, R2, and R3)

R0 is a 16-bit register for transfer, arithmetic, and logic operations. The same applies to R1 to R3. R0 can be split into high-order bits (R0H) and low-order bits (R0L) to be used separately as 8-bit data registers. R1H and R1L are analogous to R0H and R0L. R2 can be combined with R0 and used as a 32-bit data register (R2R0). R3R1 is analogous to R2R0.

### 2.2 Address Registers (A0 and A1)

A0 is a 16-bit register for address register indirect addressing and address register relative addressing. It is also used for transfer, arithmetic, and logic operations. A1 is analogous to A0. A1 can be combined with A0 to be used as a 32-bit address register (A1A0).

### 2.3 Frame Base Register (FB)

FB is a 16-bit register for FB relative addressing.

#### 2.4 Interrupt Table Register (INTB)

INTB is a 20-bit register that indicates the start address of an interrupt vector table.

### 2.5 Program Counter (PC)

PC is 20 bits wide and indicates the address of the next instruction to be executed.

# 2.6 User Stack Pointer (USP) and Interrupt Stack Pointer (ISP)

The stack pointers (SP), USP, and ISP, are each 16 bits wide. The U flag of FLG is used to switch between USP and ISP.

#### 2.7 Static Base Register (SB)

SB is a 16-bit register for SB relative addressing.

#### 2.8 Flag Register (FLG)

FLG is an 11-bit register indicating the CPU state.

# 2.8.1 Carry Flag (C)

The C flag retains carry, borrow, or shift-out bits that have been generated by the arithmetic and logic unit.

#### 2.8.2 Debug Flag (D)

The D flag is for debugging only. Set it to 0.

# 2.8.3 Zero Flag (Z)

The Z flag is set to 1 when an arithmetic operation results in 0; otherwise to 0.

# 2.8.4 Sign Flag (S)

The S flag is set to 1 when an arithmetic operation results in a negative value; otherwise to 0.

#### 2.8.5 Register Bank Select Flag (B)

Register bank 0 is selected when the B flag is 0. Register bank 1 is selected when this flag is set to 1.

#### 2.8.6 Overflow Flag (O)

The O flag is set to 1 when an operation results in an overflow; otherwise to 0.



#### 2.8.7 Interrupt Enable Flag (I)

The I flag enables maskable interrupts.

Interrupt are disabled when the I flag is set to 0, and are enabled when the I flag is set to 1. The I flag is set to 0 when an interrupt request is acknowledged.

### 2.8.8 Stack Pointer Select Flag (U)

ISP is selected when the U flag is set to 0; USP is selected when the U flag is set to 1. The U flag is set to 0 when a hardware interrupt request is acknowledged or the INT instruction of software interrupt numbers 0 to 31 is executed.

### 2.8.9 Processor Interrupt Priority Level (IPL)

IPL is 3 bits wide and assigns processor interrupt priority levels from level 0 to level 7. If a requested interrupt has higher priority than IPL, the interrupt is enabled.

#### 2.8.10 Reserved Bit

If necessary, set to 0. When read, the content is undefined.

# 3. Memory

# 3.1 R8C/26 Group

Figure 3.1 is a Memory Map of R8C/26 Group. The R8C/26 group has 1 Mbyte of address space from addresses 00000h to FFFFFh.

The internal ROM is allocated lower addresses, beginning with address 0FFFFh. For example, a 16-Kbyte internal ROM area is allocated addresses 0C000h to 0FFFFh.

The fixed interrupt vector table is allocated addresses 0FFDCh to 0FFFFh. They store the starting address of each interrupt routine.

The internal RAM is allocated higher addresses beginning with address 00400h. For example, a 1-Kbyte internal RAM area is allocated addresses 00400h to 007FFh. The internal RAM is used not only for storing data but also for calling subroutines and as stacks when interrupt requests are acknowledged.

Special function registers (SFRs) are allocated addresses 00000h to 002FFh. The peripheral function control registers are allocated here. All addresses within the SFR, which have nothing allocated are reserved for future use and cannot be accessed by users.



Figure 3.1 Memory Map of R8C/26 Group



# 3.2 R8C/27 Group

Figure 3.2 is a Memory Map of R8C/27 Group. The R8C/27 group has 1 Mbyte of address space from addresses 00000h to FFFFFh.

The internal ROM (program ROM) is allocated lower addresses, beginning with address 0FFFFh. For example, a 16-Kbyte internal ROM area is allocated addresses 0C000h to 0FFFFh.

The fixed interrupt vector table is allocated addresses 0FFDCh to 0FFFFh. They store the starting address of each interrupt routine.

The internal ROM (data flash) is allocated addresses 02400h to 02BFFh.

The internal RAM area is allocated higher addresses, beginning with address 00400h. For example, a 1-Kbyte internal RAM is allocated addresses 00400h to 007FFh. The internal RAM is used not only for storing data but also for calling subroutines and as stacks when interrupt requests are acknowledged.

Special function registers (SFRs) are allocated addresses 00000h to 002FFh. The peripheral function control registers are allocated here. All addresses within the SFR, which have nothing allocated are reserved for future use and cannot be accessed by users.



Figure 3.2 Memory Map of R8C/27 Group

#### **Special Function Registers (SFRs)** 4.

An SFR (special function register) is a control register for a peripheral function. Tables 4.1 to 4.7 list the special function registers.

Address	Register	Symbol	After reset
0000h			
0001h			
0002h			
0003h			
0004h	Processor Mode Register 0	PM0	00h
0005h	Processor Mode Register 1	PM1	00h
0006h	System Clock Control Register 0	CM0	01101000b
0007h	System Clock Control Register 1	CM1	0010000b
0008h			
0009h			
000Ah	Protect Register	PRCR	00h
000Bh			
000Ch	Oscillation Stop Detection Register	OCD	00000100b
000Dh	Watchdog Timer Reset Register	WDTR	XXh
000Eh	Watchdog Timer Start Register	WDTS	XXh
000Eh	Watchdog Timer Control Register	WDC	00X1111b
0010h	Address Match Interrupt Register 0	RMADO	00h
0011h			00h
0012h	-		00h
0012h	Address Match Interrupt Enable Register	AIER	00h
0014h	Address Match Interrupt Register 1	RMAD1	00h
0014h	Address Match Interrupt Register 1	KINADI	00h
0016h	_		00h
0010h			0011
0017h			
0018h			
0019h			
001An			
001Bh	Count Source Directorian Mode Register	CSPR	00h
00101	Count Source Protection Mode Register	COFR	
			1000000b <sup>(2)</sup>
001Dh			
001Eh			
001Fh			
0020h			
0021h			
0022h			
0023h	High-Speed On-Chip Oscillator Control Register 0	FRA0	00h
0024h	High-Speed On-Chip Oscillator Control Register 1	FRA1	When shipping
0025h	High-Speed On-Chip Oscillator Control Register 2	FRA2	00h
0026h			
0027h			
0028h	Clock Prescaler Reset Flag	CPSRF	00h
0029h	High-Speed On-Chip Oscillator Control Register 4 <sup>(3)</sup>	FRA4	When shipping
002Ah			
002Bh	High-Speed On-Chip Oscillator Control Register 6 <sup>(3)</sup>	FRA6	When shipping
002Ch	High-Speed On-Chip Oscillator Control Register 7 <sup>(3)</sup>	FRA7	When shipping
002Dh			
002Dh 002Eh			

#### Table 4.1 SFR Information (1)<sup>(1)</sup>

X: Undefined NOTES:

1. The blank regions are reserved. Do not access locations in these regions.

2. The CSPROINI bit in the OFS register is set to 0.

3. In J, K version these regions are reserved. Do not access locations in these regions.

#### Table 4.2SFR Information (2)<sup>(1)</sup>

Address	Register	Symbol	After reset
0030h	-		
0031h	Voltage Detection Register 1 (2)	VCA1	00001000b
0032h	Voltage Detection Register 2 <sup>(2)</sup>	VCA2	<ul> <li>N, D version 00h<sup>(3)</sup> 00100000b<sup>(4)</sup></li> <li>J, K version 00h<sup>(7)</sup> 0100000b<sup>(8)</sup></li> </ul>
0033h			01000000000
0034h			
0035h			
0036h	Voltage Monitor 1 Circuit Control Register (5)	VW1C	N, D version 00001000b     J, K version 0000X000b <sup>(7)</sup> 0100X001b <sup>(8)</sup>
0037h	Voltage Monitor 2 Circuit Control Register (5)	VW2C	00h
0038h	Voltage Monitor 0 Circuit Control Register <sup>(6)</sup>	VW0C	0000X000b <sup>(3)</sup> 0100X001b <sup>(4)</sup>
0039h			
003Fh			
0040h			
0041h			
0042h			
0043h			
0044h			
0045h			
0046h			
0047h	Timer RC Interrupt Control Register	TRCIC	XXXXX000b
0048h			
0049h			
004Ah	Timer RE Interrupt Control Register	TREIC	XXXXX000b
004Bh			
004Ch			
004Dh	Key Input Interrupt Control Register	KUPIC	XXXXX000b
004Eh	A/D Conversion Interrupt Control Register	ADIC	XXXXX000b
004Fh 0050h	SSU/IIC bus Interrupt Control Register <sup>(9)</sup>	SSUIC/IICIC	XXXXX000b
0050h	UART0 Transmit Interrupt Control Register	SOTIC	XXXXX000b
0051h	UARTO Receive Interrupt Control Register	SORIC	XXXXX000b
0052h	UART1 Transmit Interrupt Control Register	SITIC	XXXXX000b
0054h	UART1 Receive Interrupt Control Register	SIRIC	XXXXX000b
0055h		51116	XXXXX0000D
0055h	Timer RA Interrupt Control Register	TRAIC	XXXXX000b
0050h			
0058h	Timer RB Interrupt Control Register	TRBIC	XXXXX000b
0059h	INT1 Interrupt Control Register	INTIIC	XX00X000b
005Ah	INT3 Interrupt Control Register	INT3IC	XX00X000b
005Bh			
005Ch			
005Dh	INT0 Interrupt Control Register	INTOIC	XX00X000b
005Eh			

006Fh 0070h

0060h

#### 007Fh

X: Undefined

NOTES:

1. The blank regions are reserved. Do not access locations in these regions.

2. (N, D version) Software reset, watchdog timer reset, voltage monitor 1 reset, or voltage monitor 2 reset do not affect this register.

(J, K version) Software reset, watchdog timer reset, or voltage monitor 2 reset do not affect this register.

3. The LVD0ON bit in the OFS register is set to 1 and hardware reset.

4. Power-on reset, voltage monitor 0 reset or the LVD0ON bit in the OFS register is set to 0, and hardware reset.

5. (N, D version) Software reset, watchdog timer reset, voltage monitor 1 reset, or voltage monitor 2 reset do not affect b2 and b3.

(J, K version) Software reset, watchdog timer reset, or voltage monitor 2 reset do not affect b2 and b3.

6. (N, D version) Software reset, watchdog timer reset, voltage monitor 1 reset, or voltage monitor 2 reset do not affect this register.

(J, K version) These regions are reserved. Do not access locations in these regions.

7. The LVD1ON bit in the OFS register is set to 1 and hardware reset.

8. Power-on reset, voltage monitor 1 reset, or the LVD1ON bit in the OFS register is set to 0 and hardware reset.

9. Selected by the IICSEL bit in the PMR register.



Address	Register	Symbol	After reset
0080h			
0081h			
0082h			
0083h			
0084h			
0085h			
0086h			
0087h			
0088h			
0089h			
0089h			
008Bh			
008Ch			
008Dh			
008Eh			
008Fh			
0090h			
0091h			
0092h			
0093h			
0094h			
0095h			
0096h			1
0097h			
0098h			
0099h			+
0099h			
009An			
009Ch			
009Dh			
009Eh			
009Fh			
00A0h	UART0 Transmit/Receive Mode Register	U0MR	00h
00A1h	UART0 Bit Rate Register	U0BRG	XXh
00A2h	UART0 Transmit Buffer Register	U0TB	XXh
00A3h			XXh
00A4h	UART0 Transmit/Receive Control Register 0	U0C0	00001000b
00A5h	UART0 Transmit/Receive Control Register 1	U0C1	00000010b
00A6h	UART0 Receive Buffer Register	UORB	XXh
00A7h		00112	XXh
00A8h	UART1 Transmit/Receive Mode Register	U1MR	00h
00A8h	UART1 Bit Rate Register	U1BRG	XXh
00AAh	UART1 Transmit Buffer Register	U1TB	XXh
00ABh			XXh
00ACh	UART1 Transmit/Receive Control Register 0	U1C0	00001000b
00ADh	UART1 Transmit/Receive Control Register 1	U1C1	00000010b
00AEh	UART1 Receive Buffer Register	U1RB	XXh
00AFh			XXh
00B0h			
00B1h			
00B2h			
00B3h			
00B4h			
00B5h			
00B6h			
00B0h			+
00B7h	SS Control Deviator II / IIC hus Control Deviator 4 <sup>(2)</sup>	SSCRH / ICCR1	00h
	SS Control Register H / IIC bus Control Register 1 <sup>(2)</sup>		
00B9h	SS Control Register L / IIC bus Control Register 2 <sup>(2)</sup>	SSCRL / ICCR2	01111101b
00BAh	SS Mode Register / IIC bus Mode Register <sup>(2)</sup>	SSMR / ICMR	00011000b
00BBh	SS Enable Register / IIC bus Interrupt Enable Register <sup>(2)</sup>	SSER / ICIER	00h
00BCh	SS Status Register / IIC bus Status Register <sup>(2)</sup>	SSSR / ICSR	00h / 0000X000b
00BDh	SS Mode Register 2 / Slave Address Register <sup>(2)</sup>	SSMR2 / SAR	00h
00BDh		SSIMR2 / SAR	FFh
00BEh	SS Transmit Data Register / IIC bus Transmit Data Register <sup>(2)</sup> SS Receive Data Register / IIC bus Receive Data Register <sup>(2)</sup>	SSTDR / ICDRT SSRDR / ICDRR	
			FFh

#### SFR Information (3)<sup>(1)</sup> Table 4.3

NOTES:
1. The blank regions are reserved. Do not access locations in these regions.
2. Selected by the IICSEL bit in the PMR register.



Address	Register	Symbol	After reset
00C0h	A/D Register	AD	XXh
00C0h		70	XXh
00C2h			
00C2h			
00C3h			
00C4n			
00C6h			
00C7h			
00C8h			
00C9h			
00CAh			
00CBh			
00CCh			
00CDh			
00CEh			
00CFh			
00D0h			
00D1h			
00D2h			
00D3h			
00D4h	A/D Control Register 2	ADCON2	00h
00D5h			
00D6h	A/D Control Register 0	ADCON0	00h
00D7h	A/D Control Register 1	ADCON1	00h
00D8h			
00D9h			
00DAh			
00DBh			
00DCh			
00DDh			
00DEh			
00DFh			
00E0h	Port P0 Register	P0	00h
00E0h	Port P1 Register	P1	00h
00E1h	Port P0 Direction Register	PD0	00h
00E3h	Port P1 Direction Register	PD1	00h
00E3h		FDI	0011
00E4n	Dort D2 Desister	D2	006
	Port P3 Register	P3	00h
00E6h		550	
00E7h	Port P3 Direction Register	PD3	00h
00E8h	Port P4 Register	P4	00h
00E9h	Port P5 Register	P5	00h
00EAh	Port P4 Direction Register	PD4	00h
00EBh	Port P5 Direction Register	PD5	00h
00ECh			
00EDh			
00EEh			
00EFh			
00F0h			
00F1h			
00F2h			
00F3h			
00F4h			
00F5h	Pin Select Register 1	PINSR1	00h
00F6h	Pin Select Register 2	PINSR2	00h
00F7h	Pin Select Register 3	PINSR3	00h
00F8h	Port Mode Register	PMR	00h
00F9h	External Input Enable Register	INTEN	00h
00FAh	INT Input Filter Select Register	INTF	00h
00FBh	Key Input Enable Register	KIEN	00h
00FCh	Pull-Up Control Register 0	PUR0	00h
00FDh	Pull-Up Control Register 1	PUR1	00h
00FEh	Port P1 Drive Capacity Control Register <sup>(2)</sup>	P1DRR	00h
00FFh			
UUFFN			

#### SFR Information (4)<sup>(1)</sup> Table 4.4

X: Undefined

X: Underined
NOTES:
1. The blank regions are reserved. Do not access locations in these regions.
2. In J, K version these regions are reserved. Do not access locations in these regions.

Table 4.5	SFR	Information (5) <sup>(1)</sup>
Table 4.5	SLK	mormation (5)(*)

Address	Register	Symbol	After reset
0100h	Timer RA Control Register	TRACR	00h
0101h	Timer RA I/O Control Register	TRAIOC	00h
0102h	Timer RA Mode Register	TRAMR	00h
0103h	Timer RA Prescaler Register	TRAPRE	FFh
0104h	Timer RA Register	TRA	FFh
010411 0105h		TKA	1111
0106h	LIN Control Register	LINCR	00h
0107h	LIN Status Register	LINST	00h
0108h	Timer RB Control Register	TRBCR	00h
0109h	Timer RB One-Shot Control Register	TRBOCR	00h
010Ah	Timer RB I/O Control Register	TRBIOC	00h
010Bh	Timer RB Mode Register	TRBMR	00h
010Ch	Timer RB Prescaler Register	TRBPRE	FFh
010Dh	Timer RB Secondary Register	TRBSC	FFh
010Eh	Timer RB Primary Register	TRBPR	FFh
010En		TKBER	1111
0110h			
0111h			
0112h			
0113h			
0114h			
0115h			
0116h			
0117h			
0118h	Timer RE Second Data Register / Counter Data Register	TRESEC	00h
0119h	Timer RE Minute Data Register / Compare Data Register	TREMIN	00h
		TREHR	
011Ah	Timer RE Hour Data Register <sup>(2)</sup>		00h
011Bh	Timer RE Day of Week Data Register <sup>(2)</sup>	TREWK	00h
011Ch	Timer RE Control Register 1	TRECR1	00h
011Dh	Timer RE Control Register 2	TRECR2	00h
011Eh	Timer RE Count Source Select Register	TRECSR	00001000b
011Fh			
0120h	Timer RC Mode Register	TRCMR	01001000b
0120h	Timer RC Control Register 1	TRCCR1	00h
	Timer RC Interrupt Enable Register	TRCIER	01110000b
0122h			
0123h	Timer RC Status Register	TRCSR	01110000b
0124h	Timer RC I/O Control Register 0	TRCIOR0	10001000b
0125h	Timer RC I/O Control Register 1	TRCIOR1	10001000b
0126h	Timer RC Counter	TRC	00h
0127h			00h
0128h	Timer RC General Register A	TRCGRA	FFh
0129h			FFh
012Ah	Timer RC General Register B	TRCGRB	FFh
012An		moone	FFh
	Timer RC General Register C	TROOPC	FFh
012Ch		TRCGRC	
012Dh			FFh
012Eh	Timer RC General Register D	TRCGRD	FFh
012Fh			FFh
0130h	Timer RC Control Register 2	TRCCR2	00011111b
0131h	Timer RC Digital Filter Function Select Register	TRCDF	00h
0132h	Timer RC Output Master Enable Register	TRCOER	0111111b
0133h			
0134h			
0135h			
0135h			
0137h			
0138h			
0139h			
013Ah			
013Bh			
013Ch			
013Dh			

The blank regions are reserved. Do not access locations in these regions.
 In J, K version these regions are reserved. Do not access locations in these regions.

Address         Symbol         After reset           0140h	0140h 0141h 0142h 0143h 0144h 0145h 0146h	Register	Symbol	After reset
0141h	0141h 0142h 0143h 0144h 0145h 0146h			
0142h	0142h 0143h 0144h 0145h 0146h			
0143h          0144h          0145h          0147h          0148h          0148h          0148h          0148h          0148h          0148h          0142h          015h	0143h 0144h 0145h 0146h			
0144h            0145h            0144h            0147h            0148h            0148h            0148h            0148h            0148h            0148h            0142h            0147h            0147h            0147h            0158h            0158h            0158h            0158h            0158h            0158h            0158h            0168h            0168h            0168h	0144h 0145h 0146h			
0148h          0148h          0148h          0148h          0148h          0148h          0148h          0148h          0148h          0142h          0144h          0152h          0153h          0158h          0158h          0158h          0158h          0158h          0158h          0158h          0158h          0162h <td< th=""><th>0145h 0146h</th><th></th><th></th><th>1</th></td<>	0145h 0146h			1
0148h          0148h          0148h          0148h          0148h          0148h          0148h          0148h          0148h          0142h          0144h          0152h          0153h          0158h          0158h          0158h          0158h          0158h          0158h          0158h          0158h          0162h <td< th=""><th>0145h 0146h</th><th></th><th></th><th></th></td<>	0145h 0146h			
0148h             0148h             0148h             0148h             0148h             0148h             0142h             0142h             0142h             0142h             0142h             014Fh             015h              015h               015h                015h                 015h   <	0146h			
0147n            0148h            0148h            0148h            0148h            0148h            0148h            0142h            0142h            0142h            0148h            0148h            0148h            0148h            0148h            0148h            0148h            0148h            0148h            0158h            0158h            0158h            0158h            0158h            0152h				
0148h            0144h            0144h            0144h            0142h            0142h            0142h            0142h            0142h            0142h            0144h            0145h            015h            015h<	0147h			
0143h            0153h            0153h            0153h            0153h            0153h            0153h            0153h            0153h            0153h            0158h            0168h            0168h				
014Ah            014Ah            014Ah            014Ah            014Ah            014Ah            014Ah            014Ah            015Ah	0149h			
0142h            0142h            0142h            0142h            0142h            0142h            0153h            0158h	014Ah			4
014Ch            014Ah            014Ah            014Ah            015h            016h            016h            016h            016h            016h            016h            016h            016h            016h	014Rh			
014bh	014Dh			
014Fh            015h            016h	01401			
014Ph	014Dh			
0150h	014Eh			
0151h				
0152h				
0153h            0155h            0155h            0156h            0157h            0158h            0163h            0163h            0163h            0163h            0164h            0168h            0168h            0168h            0168h            0168h            0168h            0168h            0168h            0168h            0170h				
0154h            0155h            0157h            0157h            0158h            0169h            0161h            0162h            0168h				
0155h          0155h          0157h          0158h          0158h          0158h          0158h          0158h          0158h          0158h          0158h          0158h          0159h          0159h          0158h          0158h          0158h          0158h          0160h          0161h          0162h          0163h          0164h <td< th=""><th></th><th></th><th></th><th></th></td<>				
0155h          0155h          0157h          0158h          0158h          0158h          0158h          0158h          0158h          0158h          0158h          0158h          0159h          0159h          0158h          0158h          0158h          0158h          0160h          0161h          0162h          0163h          0164h <td< th=""><th>0154h</th><th></th><th></th><th></th></td<>	0154h			
0157h	0155h			
0157h          0158h          0159h          015Ah          015Bh          015Ch          015Dh          015Eh          015Fh          015Fh          0160h          0161h          0162h          0163h          0163h          0168h          0168h <td< th=""><th>0156h</th><th></th><th></th><th></th></td<>	0156h			
0158h	0157h		1	
0159h			1	
015Ah          015Bh          015Dh          015Dh          015Dh          015Fh          016Ch          016Ch          016Th          016Bh          016Bh          016Bh          016Dh          016Dh          016Dh          016Dh          016Dh          016Dh          016Dh          017Dh          017Th <td< th=""><th></th><th></th><th></th><th></th></td<>				
015Ch				
015Ch            015Dh            015Fh            0160h            0161h            0162h            0163h            0163h            0163h            0163h            0163h            0166h            0166h            0168h            0168h            0168h            0168h            0168h            0168h            0168h            016Bh            016Bh            016Bh            016Bh            016Bh            016Bh            016Ch            016Eh            0170h            0170h            0172h            0172h            0173h            0174h	015Rh			
015Dh          015Fh          0160h          0161h          0162h          0163h          0163h          0163h          0163h          0163h          0163h          0166h          0166h          0167h          0168h          0168h          0168h          0168h          016Bh          016Bh          016Bh          016Bh          016Bh          016Bh          016Bh          016Ch          016Ch          0170h          0177h          0177h          0177h          0177h          0177h          0177h          0178h          0178h <th></th> <th></th> <th></th> <th></th>				
015Eh	01501			
015Fh            0160h            0161h            0162h            0163h            0163h            0163h            0165h            0166h            0166h            0166h            0168h            0168h            0168h            0168h            0168h            0168h            016Bh            016Bh            016Bh            016Bh            016Bh            016Bh            016Bh            0170h            0170h            0170h            0177h            0177h            0177h            0177h            0178h            0178h            0178h <th></th> <th></th> <th></th> <th></th>				
0160h            0161h            0162h            0163h            0163h            0164h            0165h            0166h            0167h            0168h            0168h            0168h            0168h            0168h            0168h            0168h            016Bh            016Bh            016Ch            016Dh            016Eh            016Fh            016Fh            0170h            0172h            0172h            0173h            0175h            0177h            0178h            0178h            0178h				
0161h            0162h            0163h            0164h            0165h            0166h            0166h            0167h            0168h            016Ch            016Ch            016Eh            016Eh            0170h            0170h            0172h            0173h            0173h            0177h            0177h            0177h            0177h            0178h            0179h <th></th> <th></th> <th></th> <th></th>				
0162h				
0163h				
0164h				
0165h				
0166h				
0167h            0168h            0169h            016Ah            016Ah            016Bh            016Ch            016Ch            016Ch            016Ch            016Fh            016Fh            0170h            0177h            0172h            0173h            0175h            0177h            0178h            0179h            0179h				
0168h            0169h            016Ah            016Bh            016Bh            016Ch            016Dh            016Eh            016Fh            016Fh            016Fh            0170h            0177h            0173h            0173h            0175h            0176h            0177h            0178h            0179h            0179h				
0169h	0167h			
0169h	0168h			
016Ah	0169h			
016Bh            016Ch            016Dh            016Eh            016Fh            0170h            0171h            0172h            0173h            0175h            0175h            0177h            0178h            0178h            0178h            0179h            0179h				
016Ch	016Bh			
016Dh            016Eh            016Fh            0170h            0170h            0171h            0172h            0173h            0174h            0175h            0175h            0175h            0176h            0177h            0178h            0179h            0179h				
016Eh	016Dh			
016Fh				
0170h	016Eh			
0171h				
0172h				l
0173h				ļ
0174h				
0175h				
0176h				
0177h				
0177h				
0179h 017Ah 017Ah	0177h			
0179h 017Ah 017Ah	0178h			
017Ah			İ	
			1	t
				1
017Ch				ł
017Dh				l
				l
017Eh				ļ
	017Fh			

# Table 4.6SFR Information (6)<sup>(1)</sup>

NOTE:

1. The blank regions are reserved. Do not access locations in these regions.

Address	Register	Symbol	After reset
0180h	Register	Symbol	Allel Tesel
0180h			
0181h			
0182h			
0183h			
0185h			
0185h			
01801 0187h			
0187h			
0188h			
0189h			
018An			
018Dh			
018Dh			
018Eh			
018Eh			
018111 0190h			
01901 0191h			
0192h			
0193h			
0194h			
0195h			
0196h			
0197h			
0198h			
0199h			
019Ah			
019Bh			
019Ch			
019Dh			
019Eh			
019Fh			
01A0h			
01A1h			
01A2h			
01A3h			
01A4h			
01A5h			
01A6h			
01A7h			
01A8h			
01A9h			
01AAh			
01ABh			
01ACh			
01ADh			
01AEh			
01AFh			
01B0h			
01B1h			
01B2h			
01B3h	Flash Memory Control Register 4	FMR4	0100000b
01B4h			
01B5h	Flash Memory Control Register 1	FMR1	1000000Xb
01B6h			
01B7h	Flash Memory Control Register 0	FMR0	0000001b
01B8h			
01B9h		1	
01BAh			
01BBh			
01BCh			
01BDh			
01001			
()1KEn			
01BEh 01BFh			

### Table 4.7SFR Information (7)<sup>(1)</sup>

FFFFh Option Function Select Register

X: Undefined

NOTES:

1. The blank regions are reserved. Do not access locations in these regions.

2. The OFS register cannot be changed by a program. Use a flash programmer to write to it.



OFS

(Note 2)

# 5. Electrical Characteristics

# 5.1 N, D Version

#### Table 5.1 Absolute Maximum Ratings

Symbol	Parameter	Condition	Rated Value	Unit
Vcc/AVcc	Supply voltage		-0.3 to 6.5	V
VI	Input voltage		-0.3 to Vcc + 0.3	V
Vo	Output voltage		-0.3 to Vcc + 0.3	V
Pd	Power dissipation	Topr = 25°C	500	mW
Topr	Operating ambient temperature		-20 to 85 (N version) / -40 to 85 (D version)	°C
Tstg	Storage temperature		-65 to 150	°C

#### Table 5.2 Recommended Operating Conditions

Symbol		Parameter	Conditions		Standard		Unit
Symbol		arameter	Conditions	Min.	Тур.	Max.	Unit
Vcc/AVcc	Supply voltage			2.2	-	5.5	V
Vss/AVss	Supply voltage			-	0	-	V
Vih	Input "H" voltage			0.8 Vcc	-	Vcc	V
VIL	Input "L" voltage			0	-	0.2 Vcc	V
IOH(sum)	Peak sum output "H" current	Sum of all pins IOH(peak)		-	_	-160	mA
IOH(sum)	Average sum output "H" current	Sum of all pins IOH(avg)		-	-	-80	mA
IOH(peak)	Peak output "H"	Except P1_0 to P1_7		-	-	-10	mA
	current	P1_0 to P1_7		-	-	-40	mA
IOH(avg)	Average output	Except P1_0 to P1_7		-	-	-5	mA
	"H" current	P1_0 to P1_7		-	-	-20	mA
IOL(sum)	Peak sum output "L" currents	Sum of all pins IOL(peak)		-	-	160	mA
IOL(sum)	Average sum output "L" currents	Sum of all pins IOL(avg)		-	-	80	mA
IOL(peak)	Peak output "L"	Except P1_0 to P1_7		-	-	10	mA
	currents	P1_0 to P1_7		-	-	40	mA
IOL(avg)	Average output	Except P1_0 to P1_7		-	_	5	mA
	"L" current	P1_0 to P1_7		-	-	20	mA
f(XIN)	XIN clock input osc	illation frequency	$3.0 \text{ V} \leq \text{Vcc} \leq 5.5 \text{ V}$	0	-	20	MHz
			$2.7 \text{ V} \leq \text{Vcc} < 3.0 \text{ V}$	0	-	10	MHz
			$2.2~V \leq Vcc < 2.7~V$	0	-	5	MHz
f(XCIN)	XCIN clock input or	scillation frequency	$2.2 \text{ V} \leq \text{Vcc} \leq 5.5 \text{ V}$	0	-	70	kHz
-	System clock	OCD2 = 0	$3.0 \text{ V} \leq \text{Vcc} \leq 5.5 \text{ V}$	0	-	20	MHz
		XIN clock selected	$2.7 \text{ V} \leq \text{Vcc} < 3.0 \text{ V}$	0	-	10	MHz
			$2.2 \text{ V} \leq \text{Vcc} < 2.7 \text{ V}$	0	-	5	MHz
		OCD2 = 1 On-chip oscillator clock selected	FRA01 = 0 Low-speed on-chip oscillator clock selected	-	125	-	kHz
			$\begin{array}{l} \mbox{FRA01 = 1} \\ \mbox{High-speed on-chip} \\ \mbox{oscillator clock selected} \\ \mbox{3.0 V} \le Vcc \le 5.5 \ V \end{array}$	-	-	20	MHz
			$\begin{array}{l} \mbox{FRA01} = 1 \\ \mbox{High-speed on-chip} \\ \mbox{oscillator clock selected} \\ \mbox{2.7 V} \le Vcc \le 5.5 \ V \end{array}$	-	-	10	MHz
			$\begin{array}{l} \mbox{FRA01} = 1 \\ \mbox{High-speed on-chip} \\ \mbox{oscillator clock selected} \\ \mbox{2.2 V} \leq Vcc \leq 5.5 V \end{array}$	-	_	5	MHz

NOTES:

1. Vcc = 2.2 to 5.5 V at Topr = -20 to  $85^{\circ}$ C (N version) / -40 to  $85^{\circ}$ C (D version), unless otherwise specified.

2. The average output current indicates the average value of current measured during 100 ms.

Cumphiel		Denementen	Conditions	Standard			11.2
Symbol		Parameter	Conditions	Min.	Тур.	Max.	Unit
-	Resolution		Vref = AVCC	-	-	10	Bits
-	Absolute	10-bit mode	$\phi$ AD = 10 MHz, Vref = AVCC = 5.0 V	-	-	±3	LSB
	accuracy	8-bit mode	$\phi$ AD = 10 MHz, Vref = AVCC = 5.0 V	-	-	±2	LSB
		10-bit mode	$\phi$ AD = 10 MHz, Vref = AVCC = 3.3 V	-	-	±5	LSB
		8-bit mode	$\phi$ AD = 10 MHz, Vref = AVCC = 3.3 V	-	-	±2	LSB
		10-bit mode	$\phi$ AD = 5 MHz, Vref = AVCC = 2.2 V	-	-	±5	LSB
		8-bit mode	$\phi$ AD = 5 MHz, Vref = AVCC = 2.2 V	-	-	±2	LSB
Rladder	Resistor ladder		Vref = AVCC	10	-	40	kΩ
tconv	Conversion time	10-bit mode	$\phi$ AD = 10 MHz, Vref = AVCC = 5.0 V	3.3	-	-	μs
		8-bit mode	$\phi$ AD = 10 MHz, Vref = AVCC = 5.0 V	2.8	-	-	μs
Vref	Reference voltag	e		2.2	-	AVcc	V
VIA	Analog input volta	age <sup>(2)</sup>		0	-	AVcc	V
-	A/D operating	Without sample and hold	Vref = AVcc = 2.7 to 5.5 V	0.25	-	10	MHz
	clock frequency	With sample and hold	Vref = AVcc = 2.7 to 5.5 V	1	-	10	MHz
		Without sample and hold	Vref = AVcc = 2.2 to 5.5 V	0.25	-	5	MHz
		With sample and hold	Vref = AVcc = 2.2 to 5.5 V	1	-	5	MHz

#### Table 5.3 A/D Converter Characteristics

NOTES:

1. AVcc = 2.2 to 5.5 V at Topr = -20 to 85°C (N version) / -40 to 85°C (D version), unless otherwise specified.

2. When the analog input voltage is over the reference voltage, the A/D conversion result will be 3FFh in 10-bit mode and FFh in 8-bit mode.



#### Figure 5.1 Ports P0, P1, and P3 to P5 Timing Measurement Circuit

Cumbal	R8C/27 Group1,000(3)timByte program time-50400µxBlock erase time-0.49sTime delay from suspend request until suspend97 + CPU clock × 6 cyclesµxInterval from erase start/restart until following suspend request650Interval from program start/restart until following suspend request0nInterval from program start/restart until following suspend request0nTime from suspend until program/erase restart3 + CPU clock x 4 cyclesµxProgram, erase voltage2.7-5.5V	Conditions		Linit		
Symbol		Unit				
-	Program/erase endurance <sup>(2)</sup>	R8C/26 Group	100 <sup>(3)</sup>	-	-	times
		R8C/27 Group	1,000 <sup>(3)</sup>	-	-	times
-	Byte program time		-	50	400	μs
-	Block erase time		-	0.4	9	S
td(SR-SUS)	Time delay from suspend request until		-	-	97 + CPU clock	μs
	suspend				× 6 cycles	
-	Interval from erase start/restart until		650	-	-	μs
	following suspend request					
-			0	-	-	ns
-			_	-		μS
-	Program, erase voltage		2.7	_	5.5	V
-	Read voltage		2.2	-	5.5	V
_	Program, erase temperature		0	-	60	°C
-	Data hold time <sup>(7)</sup>	Ambient temperature = 55°C	20	-	_	year

Table 5.4	Flash Memory (Program ROM) Electrical Characteristics
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NOTES: 1. Vcc = 2.7 to 5.5 V at Topr = 0 to  $60^{\circ}$ C, unless otherwise specified.

2. Definition of programming/erasure endurance The programming and erasure endurance is defined on a per-block basis. If the programming and erasure endurance is n (n = 100 or 1,000), each block can be erased n times. For example, if 1,024 1-byte writes are performed to different addresses in block A, a 1 Kbyte block, and then the block is erased, the programming/erasure endurance still stands at one. However, the same address must not be programmed more than once per erase operation (overwriting prohibited).

3. Endurance to guarantee all electrical characteristics after program and erase. (1 to Min. value can be guaranteed).

4. In a system that executes multiple programming operations, the actual erasure count can be reduced by writing to sequential addresses in turn so that as much of the block as possible is used up before performing an erase operation. For example, when programming groups of 16 bytes, the effective number of rewrites can be minimized by programming up to 128 groups before erasing them all in one operation. It is also advisable to retain data on the erasure endurance of each block and limit the number of erase operations to a certain number.

5. If an error occurs during block erase, attempt to execute the clear status register command, then execute the block erase command at least three times until the erase error does not occur.

- 6. Customers desiring program/erase failure rate information should contact their Renesas technical support representative.
- 7. The data hold time includes time that the power supply is off or the clock is not supplied.

Symbol	Parameter	Conditions		Unit		
Symbol	Farameter	Conditions	Min.	Тур.	Max.	Unit
-	Program/erase endurance <sup>(2)</sup>		10,000 <sup>(3)</sup>	-	-	times
-	Byte program time (program/erase endurance $\leq$ 1,000 times)		-	50	400	μS
-	Byte program time (program/erase endurance > 1,000 times)		-	65	_	μS
-	Block erase time (program/erase endurance $\leq$ 1,000 times)		-	0.2	9	S
-	Block erase time (program/erase endurance > 1,000 times)		-	0.3	_	S
td(SR-SUS)	Time delay from suspend request until suspend		-	-	97 + CPU clock × 6 cycles	μS
-	Interval from erase start/restart until following suspend request		650	-	_	μS
-	Interval from program start/restart until following suspend request		0	-	_	ns
-	Time from suspend until program/erase restart		-	_	3 + CPU clock × 4 cycles	μS
-	Program, erase voltage		2.7	-	5.5	V
-	Read voltage		2.2	-	5.5	V
_	Program, erase temperature		-20 <sup>(8)</sup>	-	85	°C
-	Data hold time <sup>(9)</sup>	Ambient temperature = 55°C	20	-	-	year

Table 5.5	Flash Memory (Data flash Block A, Block B) Electrical Characteristics <sup>(4)</sup>	I)
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1. Vcc = 2.7 to 5.5 V at Topr = -20 to 85°C (N version) / -40 to 85°C (D version), unless otherwise specified.

2. Definition of programming/erasure endurance

The programming and erasure endurance is defined on a per-block basis.

If the programming and erasure endurance is n (n = 10,000), each block can be erased n times. For example, if 1,024 1-byte writes are performed to different addresses in block A, a 1 Kbyte block, and then the block is erased, the programming/erasure endurance still stands at one.

However, the same address must not be programmed more than once per erase operation (overwriting prohibited).

3. Endurance to guarantee all electrical characteristics after program and erase. (1 to Min. value can be guaranteed).

- 4. Standard of block A and block B when program and erase endurance exceeds 1,000 times. Byte program time to 1,000 times is the same as that in program ROM.
- 5. In a system that executes multiple programming operations, the actual erasure count can be reduced by writing to sequential addresses in turn so that as much of the block as possible is used up before performing an erase operation. For example, when programming groups of 16 bytes, the effective number of rewrites can be minimized by programming up to 128 groups before erasing them all in one operation. In addition, averaging the erasure endurance between blocks A and B can further reduce the actual erasure endurance. It is also advisable to retain data on the erasure endurance of each block and limit the number of erase operations to a certain number.

6. If an error occurs during block erase, attempt to execute the clear status register command, then execute the block erase command at least three times until the erase error does not occur.

7. Customers desiring program/erase failure rate information should contact their Renesas technical support representative.

8. -40°C for D version.

9. The data hold time includes time that the power supply is off or the clock is not supplied.



Figure 5.2 Time delay until Suspend

#### Table 5.6 Voltage Detection 0 Circuit Electrical Characteristics

Symbol	Parameter	Condition	Standard			Unit
Symbol	Falanelei	Condition	Min.	Тур.	Max.	Offic
Vdet0	Voltage detection level		2.2	2.3	2.4	V
-	Voltage detection circuit self power consumption	VCA25 = 1, Vcc = 5.0 V	-	0.9	-	μΑ
td(E-A)	Waiting time until voltage detection circuit operation starts <sup>(2)</sup>		-	-	300	μS
Vccmin	MCU operating voltage minimum value		2.2	-	-	V

NOTES:

- 1. The measurement condition is Vcc = 2.2 to 5.5 V and Topr = -20 to 85°C (N version) / -40 to 85°C (D version).
- 2. Necessary time until the voltage detection circuit operates when setting to 1 again after setting the VCA25 bit in the VCA2 register to 0.

#### Table 5.7 Voltage Detection 1 Circuit Electrical Characteristics

Symbol	Parameter	Condition		Unit		
Symbol	Farameter	Condition	Min.	Тур.	Max.	Unit
Vdet1	Voltage detection level <sup>(4)</sup>	2.70	2.85	3.00	V	
-	Voltage monitor 1 interrupt request generation time <sup>(2)</sup>		-	40	-	μS
-	Voltage detection circuit self power consumption	VCA26 = 1, Vcc = 5.0 V	-	0.6	-	μA
td(E-A)	Waiting time until voltage detection circuit operation starts <sup>(3)</sup>		-	-	100	μS

NOTES:

- 1. The measurement condition is Vcc = 2.2 to 5.5 V and Topr = -20 to 85°C (N version) / -40 to 85°C (D version).
- 2. Time until the voltage monitor 1 interrupt request is generated after the voltage passes Vdet1.
- 3. Necessary time until the voltage detection circuit operates when setting to 1 again after setting the VCA26 bit in the VCA2 register to 0.

4. This parameter shows the voltage detection level when the power supply drops. The voltage detection level when the power supply rises is higher than the voltage detection level when the power supply drops by approximately 0.1 V.

#### Table 5.8 Voltage Detection 2 Circuit Electrical Characteristics

Symbol	Parameter	Condition		Unit		
Symbol	Farameter	Condition	Min.	Тур.	Max.	Unit
Vdet2	Voltage detection level		3.3	3.6	3.9	V
-	Voltage monitor 2 interrupt request generation time <sup>(2)</sup>		-	40	-	μS
-	Voltage detection circuit self power consumption	VCA27 = 1, Vcc = 5.0 V	-	0.6	-	μA
td(E-A)	Waiting time until voltage detection circuit operation starts <sup>(3)</sup>		_	-	100	μS

NOTES:

- 1. The measurement condition is Vcc = 2.2 to 5.5 V and Topr = -20 to 85°C (N version) / -40 to 85°C (D version).
- 2. Time until the voltage monitor 2 interrupt request is generated after the voltage passes Vdet2.
- 3. Necessary time until the voltage detection circuit operates after setting to 1 again after setting the VCA27 bit in the VCA2 register to 0.



Symbol	Parameter	Condition		Unit		
	Falameter	Condition	Min.	Тур.	Max.	Unit
Vpor1	Power-on reset valid voltage <sup>(4)</sup>		-	-	0.1	V
Vpor2	Power-on reset or voltage monitor 0 reset valid voltage	5		-	Vdet0	V
trth	External power Vcc rise gradient <sup>(2)</sup>		20	-	-	mV/msec

Table 5.9	Power-on Reset Circuit.	Voltage Monitor 0 Reset	Electrical Characteristics <sup>(3)</sup>

1. The measurement condition is  $T_{opr}$  = -20 to 85°C (N version) / -40 to 85°C (D version), unless otherwise specified.

2. This condition (external power Vcc rise gradient) does not apply if Vcc  $\ge$  1.0 V.

- 3. To use the power-on reset function, enable voltage monitor 0 reset by setting the LVD0ON bit in the OFS register to 0, the VW0C0 and VW0C6 bits in the VW0C register to 1 respectively, and the VCA25 bit in the VCA2 register to 1.
- 4.  $t_{w(por1)}$  indicates the duration the external power Vcc must be held below the effective voltage (Vpor1) to enable a power on reset. When turning on the power for the first time, maintain  $t_{w(por1)}$  for 30 s or more if  $-20^{\circ}C \le T_{opr} \le 85^{\circ}C$ , maintain  $t_{w(por1)}$  for 3,000 s or more if  $-40^{\circ}C \le T_{opr} < -20^{\circ}C$ .



1. When using the voltage monitor 0 digital filter, ensure that the voltage is within the MCU operation voltage range (2.2 V or above) during the sampling time.

- 2. The sampling clock can be selected. Refer to 6. Voltage Detection Circuit of Hardware Manual for details.
- 3. Vdet0 indicates the voltage detection level of the voltage detection 0 circuit. Refer to 6. Voltage Detection Circuit of Hardware Manual for details.

Figure 5.3 Reset Circuit Electrical Characteristics

Symbol	Parameter	Condition		Unit		
Symbol	Falameter	Condition	Min.	Тур.	Max.	
fOCO40M	High-speed on-chip oscillator frequency temperature • supply voltage dependence	$\label{eq:VCC} \begin{array}{l} \mbox{Vcc} = 4.75 \mbox{ to } 5.25 \mbox{ V} \\ \mbox{0}^{\circ}\mbox{C} \leq \mbox{Topr} \leq 60^{\circ}\mbox{C}^{(2)} \end{array}$	39.2	40	40.8	MHz
		$\label{eq:Vcc} \begin{array}{l} Vcc = 3.0 \ to \ 5.5 \ V \\ -20^{\circ}C \leq T_{opr} \leq 85^{\circ}C^{(2)} \end{array}$	38.8	40	41.2	MHz
		$V_{CC} = 3.0 \text{ to } 5.5 \text{ V}$ -40°C $\leq$ Topr $\leq$ 85°C <sup>(2)</sup>	38.4	40	41.6	MHz
		Vcc = 2.7  to  5.5  V -20°C $\leq$ Topr $\leq$ 85°C <sup>(2)</sup>	38	40	42	MHz
		Vcc = 2.7  to  5.5  V -40°C ≤ Topr ≤ 85°C <sup>(2)</sup>	37.6	40	42.4	MHz
		$V_{CC} = 2.2 \text{ to } 5.5 \text{ V}$ -20°C $\leq$ Topr $\leq$ 85°C <sup>(3)</sup>	35.2	40	44.8	MHz
		$\label{eq:Vcc} \begin{array}{l} Vcc = 2.2 \ to \ 5.5 \ V \\ -40^{\circ}C \leq T_{opr} \leq 85^{\circ}C^{(3)} \end{array}$	34	40	46	MHz
		$\label{eq:Vcc} \begin{array}{l} Vcc = 5.0 \ V \pm 10\% \\ -20^{\circ}C \leq T_{opr} \leq 85^{\circ}C^{(2)} \end{array}$	38.8	40	40.8	MHz
		$Vcc = 5.0 V \pm 10\%$ -40°C ≤ Topr ≤ 85°C <sup>(2)</sup>	38.4	40	40.8	MHz
	High-speed on-chip oscillator frequency when	Vcc = 5.0 V, Topr = 25°C	-	36.864	-	MHz
	correction value in FRA7 register is written to FRA1 register <sup>(4)</sup>	$V_{CC} = 3.0 \text{ to } 5.5 \text{ V}$ -20°C $\leq$ Topr $\leq$ 85°C	-3%	-	3%	%
-	Value in FRA1 register after reset		08h <sup>(3)</sup>	-	F7h <sup>(3)</sup>	-
-	Oscillation frequency adjustment unit of high- speed on-chip oscillator	Adjust FRA1 register (value after reset) to -1	-	+0.3	-	MHz
-	Oscillation stability time		-	10	100	μS
-	Self power consumption at oscillation	Vcc = 5.0 V, Topr = 25°C	-	400	-	μA

Table 5.10	High-speed On-Chip Oscillator Circuit Electrical Characteristics
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1. Vcc = 2.2 to 5.5 V, Topr = -20 to 85°C (N version) / -40 to 85°C (D version), unless otherwise specified.

2. These standard values show when the FRA1 register value after reset is assumed.

3. These standard values show when the corrected value of the FRA6 register is written to the FRA1 register.

4. This enables the setting errors of bit rates such as 9600 bps and 38400 bps to be 0% when the serial interface is used in UART mode.

#### Table 5.11 Low-speed On-Chip Oscillator Circuit Electrical Characteristics

Symbol	Parameter	Condition		Unit		
Symbol	Falameter	Condition	Min.	Тур.	Max.	Onit
fOCO-S	Low-speed on-chip oscillator frequency		30	125	250	kHz
-	Oscillation stability time		-	10	100	μS
-	Self power consumption at oscillation	Vcc = 5.0 V, Topr = 25°C	-	15	-	μA

NOTE:

1. Vcc = 2.2 to 5.5 V, Topr = -20 to 85°C (N version) / -40 to 85°C (D version), unless otherwise specified.

#### Table 5.12 Power Supply Circuit Timing Characteristics

Svmbol	Parameter	Condition	:	Unit		
Symbol	Falanetei	Condition	Min.	Тур.	Max.	Unit
td(P-R)	Time for internal power supply stabilization during power-on <sup>(2)</sup>		1	-	2000	μS
td(R-S)	STOP exit time <sup>(3)</sup>		-	-	150	μS

NOTES:

1. The measurement condition is Vcc = 2.2 to 5.5 V and  $T_{opr}$  = 25°C.

2. Waiting time until the internal power supply generation circuit stabilizes during power-on.

3. Time until system clock supply starts after the interrupt is acknowledged to exit stop mode.



Cumbal	Paramete		Conditions		Standard			
Symbol	Paramete	ſ	Conditions		Тур.	Max.		
tsucyc	SSCK clock cycle time	e		4	-	-	tCYC <sup>(2)</sup>	
tнı	SSCK clock "H" width			0.4	-	0.6	tsucyc	
tlo	SSCK clock "L" width			0.4	-	0.6	tsucyc	
trise	SSCK clock rising	Master		-	-	1	tCYC <sup>(2)</sup>	
	time	Slave		-	-	1	μs	
<b>TFALL</b>	SSCK clock falling time	Master		-	-	1	tCYC <sup>(2)</sup>	
		Slave		-	-	1	μs	
ts∪	SSO, SSI data input setup time			100	-	-	ns	
tн	SSO, SSI data input h	old time		1	-	-	tCYC <sup>(2)</sup>	
tlead	SCS setup time	Slave		1tcyc + 50	_	_	ns	
tlag	SCS hold time	Slave		1tcyc + 50	-	_	ns	
top	SSO, SSI data output	delay time		-	-	1	tCYC <sup>(2)</sup>	
tsa	SSI slave access time	SSI slave access time		-	-	1.5tcyc + 100	ns	
			$2.2 \text{ V} \leq \text{Vcc} < 2.7 \text{ V}$	-	_	1.5tcyc + 200	ns	
tOR	SSI slave out open tir	ne	$2.7~V \leq Vcc \leq 5.5~V$	_	-	1.5tcyc + 100	ns	
			$2.2 \text{ V} \leq \text{Vcc} < 2.7 \text{ V}$	-	-	1.5tcyc + 200	ns	

Table 5.13 Timing Requirements of Clock Synchronous Serial I/O with Chip Select<sup>(1)</sup>

1. Vcc = 2.2 to 5.5 V, Vss = 0 V at T<sub>opr</sub> = -20 to  $85^{\circ}$ C (N version) / -40 to  $85^{\circ}$ C (D version), unless otherwise specified. 2. 1tcrc = 1/f1(s)






	Table 5.14	Timing Requirements of I <sup>2</sup> C bus Interface <sup>(1)</sup>	
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Symbol	Parameter	Condition	Sta	Unit		
Symbol	Falameter	Condition	Min.	Тур.	Max.	
tSCL	SCL input cycle time		12tcyc + 600 <sup>(2)</sup>	-	-	ns
<b>t</b> SCLH	SCL input "H" width		3tcyc + 300 <sup>(2)</sup>	-	-	ns
tSCLL	SCL input "L" width		5tcyc + 500 <sup>(2)</sup>	-	-	ns
tsf	SCL, SDA input fall time		-	-	300	ns
tsp	SCL, SDA input spike pulse rejection time		-	-	1tcyc <sup>(2)</sup>	ns
tbuf	SDA input bus-free time		5tcyc <sup>(2)</sup>	-	-	ns
<b>t</b> STAH	Start condition input hold time		3tcyc <sup>(2)</sup>	-	-	ns
<b>t</b> STAS	Retransmit start condition input setup time		3tCYC <sup>(2)</sup>	-	-	ns
<b>t</b> STOP	Stop condition input setup time		3tCYC <sup>(2)</sup>	_	-	ns
tSDAS	Data input setup time		1tcyc + 20 <sup>(2)</sup>	-	-	ns
<b>t</b> SDAH	Data input hold time		0	_	-	ns

NOTES:

1. Vcc = 2.2 to 5.5 V, Vss = 0 V and  $T_{opr} = -20$  to 85°C (N version) / -40 to 85°C (D version), unless otherwise specified.

2. 1tcyc = 1/f1(s)





Symbol	Do	Parameter		Condition		tandard		Unit
Symbol	Pa	ameter	Condition		Min.	Тур.	Max.	Unit
Vон	Output "H" voltage	Except P1_0 to P1_7,	Iон = -5 mA		Vcc - 2.0	I	Vcc	V
		XOUT	Іон = -200 μА		Vcc - 0.5	I	Vcc	V
		P1_0 to P1_7	Drive capacity HIGH	Іон = -20 mA	Vcc - 2.0	I	Vcc	V
			Drive capacity LOW	Іон = -5 mA	Vcc - 2.0	I	Vcc	V
		XOUT	Drive capacity HIGH	Іон = -1 mA	Vcc - 2.0	I	Vcc	V
			Drive capacity LOW	Іон = -500 μА	Vcc - 2.0	I	Vcc	V
Vol	Output "L" voltage	Except P1_0 to P1_7,	IOL = 5 mA		-	I	2.0	V
		XOUT	Ιοι = 200 μΑ		-	I	0.45	V
		P1_0 to P1_7	Drive capacity HIGH	IoL = 20 mA	-	I	2.0	V
			Drive capacity LOW	IoL = 5 mA	-	I	2.0	V
		XOUT	Drive capacity HIGH	IoL = 1 mA	-	I	2.0	V
				Drive capacity LOW	IoL = 500 μA	-	I	2.0
Vt+-Vt-	Hysteresis	INT0, INT1, INT3, KI0, KI1, KI2, KI3, TRAIO, RXD0, RXD1, CLK0, CLK1, SSI, SCL, SDA, SSO			0.1	0.5	_	V
		RESET			0.1	1.0	-	V
Ін	Input "H" current		VI = 5 V, Vcc = 5 V		-	_	5.0	μA
lı∟	Input "L" current		VI = 0 V, Vcc = 5 V		-	-	-5.0	μA
Rpullup	Pull-up resistance		VI = 0 V, Vcc = 5 V		30	50	167	kΩ
RfXIN	Feedback resistance	XIN			-	1.0	-	MΩ
Rfxcin	Feedback resistance	XCIN			-	18	-	MΩ
Vram	RAM hold voltage		During stop mode		1.8	_	-	V

Table 5.15	Electrical Ch	aracteristics	(1)	[Vcc =	5 V]
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NOTE:

1. Vcc = 4.2 to 5.5 V at Topr = -20 to 85°C (N version) / -40 to 85°C (D version), f(XIN) = 20 MHz, unless otherwise specified.

# Table 5.16Electrical Characteristics (2) [Vcc = 5 V]<br/>(Topr = -20 to 85°C (N version) / -40 to 85°C (D version), unless otherwise specified.)

Symbol	Paramotor		Condition		Standar	ł	Unit
Symbol	Parameter			Min.	Тур.	Max.	Unit
(\ Si	Power supply current (Vcc = 3.3 to 5.5 V) Single-chip mode, output pins are open,	High-speed clock mode	XIN = 20 MHz (square wave) High-speed on-chip oscillator off Low-speed on-chip oscillator on = 125 kHz No division	_	10	17	mA
	other pins are Vss		XIN = 16 MHz (square wave) High-speed on-chip oscillator off Low-speed on-chip oscillator on = 125 kHz No division	_	9	15	mA
			XIN = 10 MHz (square wave) High-speed on-chip oscillator off Low-speed on-chip oscillator on = 125 kHz No division	-	6	-	mA
			XIN = 20 MHz (square wave) High-speed on-chip oscillator off Low-speed on-chip oscillator on = 125 kHz Divide-by-8	-	5	-	mA
			XIN = 16 MHz (square wave) High-speed on-chip oscillator off Low-speed on-chip oscillator on = 125 kHz Divide-by-8	_	4	-	mA
			XIN = 10 MHz (square wave) High-speed on-chip oscillator off Low-speed on-chip oscillator on = 125 kHz Divide-by-8	_	2.5	_	mA
		High-speed on-chip oscillator mode	XIN clock off High-speed on-chip oscillator on fOCO = 20 MHz Low-speed on-chip oscillator on = 125 kHz No division	_	10	15	mA
			XIN clock off High-speed on-chip oscillator on fOCO = 20 MHz Low-speed on-chip oscillator on = 125 kHz Divide-by-8	_	4	_	mA
			XIN clock off High-speed on-chip oscillator on fOCO = 10 MHz Low-speed on-chip oscillator on = 125 kHz No division	_	5.5	10	mA
			XIN clock off High-speed on-chip oscillator on fOCO = 10 MHz Low-speed on-chip oscillator on = 125 kHz Divide-by-8	_	2.5	-	mA
		Low-speed on-chip oscillator mode	XIN clock off High-speed on-chip oscillator off Low-speed on-chip oscillator on = 125 kHz Divide-by-8, FMR47 = 1	_	130	300	μA
		Low-speed clock mode	XIN clock off High-speed on-chip oscillator off Low-speed on-chip oscillator off XCIN clock oscillator on = 32 kHz FMR47 = 1	_	130	300	μA
			XIN clock off High-speed on-chip oscillator off Low-speed on-chip oscillator off XCIN clock oscillator on = 32 kHz Program operation on RAM Flash memory off, FMSTP = 1	_	30	-	μA

# Table 5.17Electrical Characteristics (3) [Vcc = 5 V]<br/>(Topr = -20 to 85°C (N version) / -40 to 85°C (D version), unless otherwise specified.)

Symbol	Deremeter	Parameter Condition					Unit
Symbol	Falameter				Тур.	Max.	Onit
Icc	Power supply current (Vcc = 3.3 to 5.5 V) Single-chip mode, output pins are open, other pins are Vss	Wait mode	XIN clock off High-speed on-chip oscillator off Low-speed on-chip oscillator on = 125 kHz While a WAIT instruction is executed Peripheral clock operation VCA27 = VCA26 = VCA25 = 0 VCA20 = 1	_	25	75	μA
			XIN clock off High-speed on-chip oscillator off Low-speed on-chip oscillator on = 125 kHz While a WAIT instruction is executed Peripheral clock off VCA27 = VCA26 = VCA25 = 0 VCA20 = 1	_	23	60	μΑ
			XIN clock off High-speed on-chip oscillator off Low-speed on-chip oscillator off XCIN clock oscillator on = 32 kHz (high drive) While a WAIT instruction is executed VCA27 = VCA26 = VCA25 = 0 VCA20 = 1	-	4.0	_	μA
			XIN clock off High-speed on-chip oscillator off Low-speed on-chip oscillator off XCIN clock oscillator on = 32 kHz (low drive) While a WAIT instruction is executed VCA27 = VCA26 = VCA25 = 0 VCA20 = 1	-	2.2	-	μA
		Stop mode	XIN clock off, $T_{opr} = 25^{\circ}C$ High-speed on-chip oscillator off Low-speed on-chip oscillator off CM10 = 1 Peripheral clock off VCA27 = VCA26 = VCA25 = 0	_	0.8	3.0	μΑ
			XIN clock off, $T_{opr} = 85^{\circ}C$ High-speed on-chip oscillator off Low-speed on-chip oscillator off CM10 = 1 Peripheral clock off VCA27 = VCA26 = VCA25 = 0	_	1.2	_	μΑ

#### Timing Requirements (Unless Otherwise Specified: Vcc = 5 V, Vss = 0 V at Topr = 25°C) [Vcc = 5 V]

#### Table 5.18 XIN Input, XCIN Input

Symbol	Parameter		Standard		
	Falanletei	Min.	Max.	Unit	
tc(XIN)	XIN input cycle time	50	-	ns	
twh(xin)	XIN input "H" width	25	-	ns	
twl(XIN)	XIN input "L" width	25	-	ns	
tc(XCIN)	XCIN input cycle time	14	-	μS	
twH(XCIN)	XCIN input "H" width	7	-	μS	
twl(xcin)	XCIN input "L" width	7	-	μS	



### Figure 5.8 XIN Input and XCIN Input Timing Diagram when Vcc = 5 V

#### Table 5.19 TRAIO Input

Symbol	Parameter		Standard		
			Max.	Unit	
tc(TRAIO)	TRAIO input cycle time	100	-	ns	
twh(traio)	TRAIO input "H" width	40	-	ns	
twl(traio)	TRAIO input "L" width	40	-	ns	



Figure 5.9 TRAIO Input Timing Diagram when Vcc = 5 V

Symbol	Parameter		Standard		
	Falallelel	Min.	Max.	Unit	
tc(CK)	CLKi input cycle time	200	-	ns	
tW(CKH)	CLKi input "H" width	100	-	ns	
tW(CKL)	CLKi input "L" width	100	-	ns	
td(C-Q)	TXDi output delay time	-	50	ns	
th(C-Q)	TXDi hold time	0	-	ns	
tsu(D-C)	RXDi input setup time	50	-	ns	
th(C-D)	RXDi input hold time	90	-	ns	

i = 0 or 1



Figure 5.10 Serial Interface Timing Diagram when Vcc = 5 V

#### Table 5.21External Interrupt INTi (i = 0, 1, 3) Input

Symbol	Parameter		Standard		
			Max.	Unit	
tw(INH)	INTi input "H" width	250(1)	-	ns	
tw(INL)	INTi input "L" width	250 <sup>(2)</sup>	-	ns	

NOTES:

1. When selecting the digital filter by the INTi input filter select bit, use an INTi input HIGH width of either (1/digital filter clock frequency × 3) or the minimum value of standard, whichever is greater.

2. When selecting the digital filter by the INTi input filter select bit, use an INTi input LOW width of either (1/digital filter clock frequency × 3) or the minimum value of standard, whichever is greater.



Figure 5.11 External Interrupt INTi Input Timing Diagram when Vcc = 5 V

Symbol	Parameter		Condition		Standard Min. Tvp. Max.			Unit
Symbol	Fala	i arameter condition		Condition		Тур.	Max.	Unit
Vон	Output "H" voltage	Except P1_0 to P1_7, XOUT	Іон = -1 mA		Vcc - 0.5	_	Vcc	V
		P1_0 to P1_7	Drive capacity HIGH	Іон = -5 mA	Vcc - 0.5	-	Vcc	V
			Drive capacity LOW	Iон = -1 mA	Vcc - 0.5	-	Vcc	V
		XOUT	Drive capacity HIGH	Iон = -0.1 mA	Vcc - 0.5	-	Vcc	V
			Drive capacity LOW	Іон = -50 μА	Vcc - 0.5	_	Vcc	V
VoL Output "L"	Output "L" voltage	Except P1_0 to P1_7, XOUT	IoL = 1 mA		-	_	0.5	V
		P1_0 to P1_7	Drive capacity HIGH	IOL = 5 mA	-	-	0.5	V
			Drive capacity LOW	IOL = 1 mA	-	-	0.5	V
		XOUT	Drive capacity HIGH	IOL = 0.1 mA	-	_	0.5	V
			Drive capacity LOW	IOL = 50 μA	-	_	0.5	V
VT+-VT-	Hysteresis	INT0, INT1, INT3, KI0, KI1, KI2, KI3, TRAIO, RXD0, RXD1, CLK0, CLK1, SSI, SCL, SDA, SSO			0.1	0.3	_	V
		RESET			0.1	0.4	-	V
Ін	Input "H" current		VI = 3 V, Vcc = 3	V	_	-	4.0	μA
lı∟	Input "L" current			V	-	_	-4.0	μA
RPULLUP	Pull-up resistance		VI = 0 V, Vcc = 3	V	66	160	500	kΩ
Rfxin	Feedback resistance	XIN			—	3.0	_	MΩ
Rfxcin	Feedback resistance	XCIN			_	18	_	MΩ
Vram	RAM hold voltage		During stop mode	9	1.8	-	-	V

NOTE:

1. Vcc = 2.7 to 3.3 V at Topr = -20 to 85°C (N version) / -40 to 85°C (D version), f(XIN) = 10 MHz, unless otherwise specified.

# Table 5.23Electrical Characteristics (4) [Vcc = 3 V]<br/>(Topr = -20 to 85°C (N version) / -40 to 85°C (D version), unless otherwise specified.)

Cumbal	Doromotor		Condition		Standar	d	المنال
Symbol	Parameter		Condition	Min.	Тур.	Max.	Unit
Icc	Power supply current (Vcc = 2.7 to 3.3 V) Single-chip mode, output pins are open.	High-speed clock mode	XIN = 10 MHz (square wave) High-speed on-chip oscillator off Low-speed on-chip oscillator on = 125 kHz No division	_	6	-	mA
	other pins are Vss		XIN = 10 MHz (square wave) High-speed on-chip oscillator off Low-speed on-chip oscillator on = 125 kHz Divide-by-8	_	2	-	mA
		High-speed on-chip oscillator	XIN clock off High-speed on-chip oscillator on fOCO = 10 MHz Low-speed on-chip oscillator on = 125 kHz No division	-	5	9	mA
		mode	XIN clock off High-speed on-chip oscillator on fOCO = 10 MHz Low-speed on-chip oscillator on = 125 kHz Divide-by-8	_	2	_	mA
		Low-speed on-chip oscillator mode	XIN clock off High-speed on-chip oscillator off Low-speed on-chip oscillator on = 125 kHz Divide-by-8, FMR47 = 1	-	130	300	μA
		Low-speed clock mode	XIN clock off High-speed on-chip oscillator off Low-speed on-chip oscillator off XCIN clock oscillator on = 32 kHz FMR47 = 1	_	130	300	μΑ
			XIN clock off High-speed on-chip oscillator off Low-speed on-chip oscillator off XCIN clock oscillator on = 32 kHz Program operation on RAM Flash memory off, FMSTP = 1	_	30	_	μΑ
		Wait mode	XIN clock off High-speed on-chip oscillator off Low-speed on-chip oscillator on = 125 kHz While a WAIT instruction is executed Peripheral clock operation VCA27 = VCA26 = VCA25 = 0 VCA20 = 1	_	25	70	μA
			XIN clock off High-speed on-chip oscillator off Low-speed on-chip oscillator on = 125 kHz While a WAIT instruction is executed Peripheral clock off VCA27 = VCA26 = VCA25 = 0 VCA20 = 1	_	23	55	μΑ
		XIN clock off High-speed on-chip oscillator off Low-speed on-chip oscillator off XCIN clock oscillator on = 32 kHz (high drive) While a WAIT instruction is executed VCA27 = VCA26 = VCA25 = 0 VCA20 = 1	_	3.8	_	μΑ	
			XIN clock off High-speed on-chip oscillator off Low-speed on-chip oscillator off XCIN clock oscillator on = 32 kHz (low drive) While a WAIT instruction is executed VCA27 = VCA26 = VCA25 = 0 VCA20 = 1	-	2.0		μA
		Stop mode	XIN clock off, $T_{opr} = 25^{\circ}C$ High-speed on-chip oscillator off Low-speed on-chip oscillator off CM10 = 1 Peripheral clock off VCA27 = VCA26 = VCA25 = 0	_	0.7	3.0	μΑ
			XIN clock off, $T_{opr} = 85^{\circ}C$ High-speed on-chip oscillator off Low-speed on-chip oscillator off CM10 = 1 Peripheral clock off VCA27 = VCA26 = VCA25 = 0	_	1.1	_	μA

#### Timing requirements (Unless Otherwise Specified: Vcc = 3 V, Vss = 0 V at Topr = 25°C) [Vcc = 3 V]

#### Table 5.24 XIN Input, XCIN Input

Symbol	Parameter	Stan	dard	Unit	
	Falanlelei	Min.	Max.	Unit	
tc(XIN)	XIN input cycle time	100	-	ns	
twh(xin)	XIN input "H" width	40	-	ns	
twl(XIN)	XIN input "L" width	40	-	ns	
tc(XCIN)	XCIN input cycle time	14	-	μs	
tWH(XCIN)	XCIN input "H" width	7	-	μs	
tWL(XCIN)	XCIN input "L" width	7	-	μs	



### Figure 5.12 XIN Input and XCIN Input Timing Diagram when Vcc = 3 V

#### Table 5.25 TRAIO Input

Symbol	Parameter	Stan	dard	Unit
	Falanielei	Min.	Max.	Onit
tc(TRAIO)	TRAIO input cycle time	300	-	ns
twh(traio)	TRAIO input "H" width	120	-	ns
twl(traio)	TRAIO input "L" width	120	-	ns



#### Figure 5.13 TRAIO Input Timing Diagram when Vcc = 3 V

Symbol	Parameter	Sta	Standard	
	Farameter	Min.	Max.	Unit
tc(CK)	CLKi input cycle time	300	-	ns
tw(CKH)	CLKi input "H" width	150	-	ns
tw(CKL)	CLKi Input "L" width	150	-	ns
td(C-Q)	TXDi output delay time	-	80	ns
th(C-Q)	TXDi hold time	0	-	ns
tsu(D-C)	RXDi input setup time	70	-	ns
th(C-D)	RXDi input hold time	90	-	ns

i = 0 or 1





#### Table 5.27 External Interrupt INTi (i = 0, 1, 3) Input

Symbol	Parameter	Stan	dard	Unit
	Falanielei	Min.	Max.	Unit
tw(INH)	INTi input "H" width	380(1)	-	ns
tw(INL)	INTi input "L" width	380(2)	-	ns

NOTES:

1. When selecting the digital filter by the INTi input filter select bit, use an INTi input HIGH width of either (1/digital filter clock frequency × 3) or the minimum value of standard, whichever is greater.

2. When selecting the digital filter by the INTi input filter select bit, use an INTi input LOW width of either (1/digital filter clock frequency x 3) or the minimum value of standard, whichever is greater.



Figure 5.15 External Interrupt INTi Input Timing Diagram when Vcc = 3 V

Symbol	Dorr	ameter	Con	dition	S	tandard		Linit
Symbol	Pala	ameter	Cond	allion	Min.	Тур.	Max.	Vinit V V V V V V V
Vон	Output "H" voltage	Except P1_0 to P1_7, XOUT	Iон = -1 mA		Vcc - 0.5	-	Vcc	V
		P1_0 to P1_7	Drive capacity HIGH	Іон = -2 mA	Vcc - 0.5	_	Vcc	V
			Drive capacity LOW	Іон = -1 mA	Vcc - 0.5	_	Vcc	V
		XOUT	Drive capacity HIGH	Іон = -0.1 mA	Vcc - 0.5	-	Vcc	V
			Drive capacity LOW	Іон = -50 μА	Vcc - 0.5	-	Vcc	V
Vol	Output "L" voltage	Except P1_0 to P1_7, XOUT	Iol = 1 mA		-	-	0.5	V
		P1_0 to P1_7	Drive capacity HIGH	IOL = 2 mA	-	_	0.5	V
			Drive capacity LOW	IOL = 1 mA	-	-	0.5	V
		XOUT	Drive capacity HIGH	IOL = 0.1 mA	-	-	0.5	V
			Drive capacity LOW	IoL = 50 μA	-	_	0.5	V
VT+-VT-	Hysteresis	INT0, INT1, INT3, KI0, KI1, KI2, KI3, TRAIO, RXD0, RXD1, CLK0, CLK1, SSI, SCL, SDA, SSO			0.05	0.3	_	V
		RESET			0.05	0.15	-	V
Ін	Input "H" current	1	VI = 2.2 V		_	_	4.0	μA
lı∟	Input "L" current		VI = 0 V		-	_	-4.0	μA
Rpullup	Pull-up resistance		VI = 0 V		100	200	600	kΩ
Rfxin	Feedback resistance	XIN			-	5	_	MΩ
Rfxcin	Feedback resistance	XCIN			-	35	-	MΩ
Vram	RAM hold voltage		During stop mod	e	1.8	-	-	V

### Table 5.28 Electrical Characteristics (5) [Vcc = 2.2 V]

NOTE:

1. Vcc = 2.2 V at Topr = -20 to 85°C (N version) / -40 to 85°C (D version), f(XIN) = 5 MHz, unless otherwise specified.

# Table 5.29Electrical Characteristics (6) [Vcc = 2.2 V]<br/>(Topr = -20 to 85°C (N version) / -40 to 85°C (D version), unless otherwise specified.)

Cumbal	Parameter	Parameter Condition	Condition	Standard			Unit
Symbol	Parameter		Condition	Min.	Тур.	Max.	Unit
Icc	Power supply current (Vcc = 2.2 to 2.7 V) Single-chip mode, output pins are open,	High-speed clock mode	XIN = 5 MHz (square wave) High-speed on-chip oscillator off Low-speed on-chip oscillator on = 125 kHz No division	-	3.5	-	mA
	other pins are Vss		XIN = 5 MHz (square wave) High-speed on-chip oscillator off Low-speed on-chip oscillator on = 125 kHz Divide-by-8	-	1.5	-	mA
		High-speed on-chip oscillator	XIN clock off High-speed on-chip oscillator on fOCO = 5 MHz Low-speed on-chip oscillator on = 125 kHz No division	-	3.5	-	mA
		mode	XIN clock off High-speed on-chip oscillator on fOCO = 5 MHz Low-speed on-chip oscillator on = 125 kHz Divide-by-8	-	1.5	-	mA
		Low-speed on-chip oscillator mode	XIN clock off High-speed on-chip oscillator off Low-speed on-chip oscillator on = 125 kHz Divide-by-8, FMR47 = 1	-	100	230	μΑ
		Low-speed clock mode	XIN clock off High-speed on-chip oscillator off Low-speed on-chip oscillator off XCIN clock oscillator on = 32 kHz FMR47 = 1	-	100	230	μΑ
			XIN clock off High-speed on-chip oscillator off Low-speed on-chip oscillator off XCIN clock oscillator on = 32 kHz Program operation on RAM Flash memory off, FMSTP = 1	-	25	_	μΑ
		Wait mode	XIN clock off High-speed on-chip oscillator off Low-speed on-chip oscillator on = 125 kHz While a WAIT instruction is executed Peripheral clock operation VCA27 = VCA26 = VCA25 = 0 VCA20 = 1	_	22	60	μA
			XIN clock off High-speed on-chip oscillator off Low-speed on-chip oscillator on = 125 kHz While a WAIT instruction is executed Peripheral clock off VCA27 = VCA26 = VCA25 = 0 VCA20 = 1	_	20	55	μA
			XIN clock off High-speed on-chip oscillator off Low-speed on-chip oscillator off XCIN clock oscillator on = $32 \text{ kHz}$ (high drive) While a WAIT instruction is executed VCA27 = VCA26 = VCA25 = 0 VCA20 = 1	_	3.0	_	μΑ
			XIN clock off High-speed on-chip oscillator off Low-speed on-chip oscillator off XCIN clock oscillator on = $32 \text{ kHz}$ (low drive) While a WAIT instruction is executed VCA27 = VCA26 = VCA25 = 0 VCA20 = 1	_	1.8	_	μA
		Stop mode	XIN clock off, $T_{opr} = 25^{\circ}C$ High-speed on-chip oscillator off Low-speed on-chip oscillator off CM10 = 1 Peripheral clock off VCA27 = VCA26 = VCA25 = 0	-	0.7	3.0	μA
			XIN clock off, $T_{opr} = 85^{\circ}C$ High-speed on-chip oscillator off Low-speed on-chip oscillator off CM10 = 1 Peripheral clock off VCA27 = VCA26 = VCA25 = 0	_	1.1	_	μA

#### Timing requirements (Unless Otherwise Specified: Vcc = 2.2 V, Vss = 0 V at Topr = 25°C) [Vcc = 2.2 V]

#### Table 5.30 XIN Input, XCIN Input

Symbol	Parameter	Stan	dard	Unit	
	Falanelei	Min.	Max.	Unit	
tc(XIN)	XIN input cycle time	200	-	ns	
twh(xin)	XIN input "H" width	90	-	ns	
twl(XIN)	XIN input "L" width	90	-	ns	
tc(XCIN)	XCIN input cycle time	14	-	μs	
tWH(XCIN)	XCIN input "H" width	7	-	μs	
tWL(XCIN)	XCIN input "L" width	7	-	μs	



### Figure 5.16 XIN Input and XCIN Input Timing Diagram when Vcc = 2.2 V

#### Table 5.31 TRAIO Input

Symbol	Parameter	Stan	dard Max.	Unit
	Falanielei	Min.		Offic
tc(TRAIO)	TRAIO input cycle time	500	-	ns
twh(traio)	TRAIO input "H" width	200	-	ns
twl(traio)	TRAIO input "L" width	200	-	ns



#### Figure 5.17 TRAIO Input Timing Diagram when Vcc = 2.2 V

Symbol	Parameter	Star	Standard		
	Parameter	Min.	Max.	Unit	
tc(CK)	CLKi input cycle time	800	_	ns	
tw(CKH)	CLKi input "H" width	400	_	ns	
tW(CKL)	CLKi input "L" width	400	-	ns	
td(C-Q)	TXDi output delay time	-	200	ns	
th(C-Q)	TXDi hold time	0	_	ns	
tsu(D-C)	RXDi input setup time	150	-	ns	
th(C-D)	RXDi input hold time	90	-	ns	

i = 0 or 1





#### Table 5.33 External Interrupt INTi (i = 0, 1, 3) Input

Symbol	Parameter		Standard		
			Max.	Unit	
tw(INH)	INTi input "H" width	1000(1)	-	ns	
tw(INL)	INTi input "L" width	1000 <sup>(2)</sup>	-	ns	

NOTES:

1. When selecting the digital filter by the INTi input filter select bit, use an INTi input HIGH width of either (1/digital filter clock frequency × 3) or the minimum value of standard, whichever is greater.

When selecting the digital filter by the INTi input filter select bit, use an INTi input LOW width of either (1/digital filter clock frequency × 3) or the minimum value of standard, whichever is greater.



Figure 5.19 External Interrupt INTi Input Timing Diagram when VCC = 2.2 V

### 5.2 J, K Version

Table 5.34	Absolute	Maximum	Ratings
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Symbol	Parameter	Condition	Rated Value	Unit
Vcc/AVcc	Supply voltage		-0.3 to 6.5	V
Vi	Input voltage		-0.3 to Vcc + 0.3	V
Vo	Output voltage		-0.3 to Vcc + 0.3	V
Pd	Power dissipation	-40 °C $\leq$ Topr $\leq$ 85 °C	300	mW
		85 °C $\leq$ Topr $\leq$ 125 °C	125	mW
Topr	Operating ambient temperature		-40 to 85 (J version) / -40 to 125 (K version)	°C
Tstg	Storage temperature		-65 to 150	°C

#### Table 5.35 Recommended Operating Conditions

Cumple al	Der		Conditions		Linit		
Symbol	Para	ameter	Conditions	Min.	Тур.	Max.	Unit
Vcc/AVcc	Supply voltage			2.7	-	5.5	V
Vss/AVss	Supply voltage			-	0	-	V
Viн	Input "H" voltage			0.8 Vcc	-	Vcc	V
VIL	Input "L" voltage			0	-	0.2 Vcc	V
IOH(sum)	Peak sum output "H" current	Sum of all pins IOH(peak)		-	-	-60	mA
IOH(peak)	Peak output "H" current			-	-	-10	mA
IOH(avg)	Average output "H" current			-	-	-5	mA
IOL(sum)	Peak sum output "L" currents	Sum of all pins IOL(peak)		-	-	60	mA
IOL(peak)	Peak output "L" currents			-	-	10	mA
IOL(avg)	Average output "L" current			-	_	5	mA
f(XIN)	XIN clock input os	cillation frequency	$3.0 \text{ V} \le \text{Vcc} \le 5.5 \text{ V}$ (other than K version)	0	-	20	MHz
			$3.0 \text{ V} \leq \text{Vcc} \leq 5.5 \text{ V}$ (K version)	0	-	16	MHz
			$2.7 \text{ V} \leq \text{Vcc} < 3.0 \text{ V}$	0	-	10	MHz
-	System clock	OCD2 = 0 XIN clock selected	3.0 V $\leq$ Vcc $\leq$ 5.5 V (other than K version)	0	-	20	MHz
			$3.0 \text{ V} \leq \text{Vcc} \leq 5.5 \text{ V}$ (K version)	0	-	16	MHz
			$2.7 \text{ V} \leq \text{Vcc} < 3.0 \text{ V}$	0	-	10	MHz
		OCD2 = 1 On-chip oscillator clock selected	FRA01 = 0 Low-speed on-chip oscillator clock selected	-	125	-	kHz
			FRA01 = 1 High-speed on-chip oscillator clock selected (other than K version)	_	_	20	MHz
			FRA01 = 1 High-speed on-chip oscillator clock selected	-	-	10	MHz

NOTES:

1. Vcc = 2.7 to 5.5 V at  $T_{opr} = -40$  to  $85^{\circ}C$  (J version) / -40 to  $125^{\circ}C$  (K version), unless otherwise specified.

2. The average output current indicates the average value of current measured during 100 ms.



Symbol		Parameter	Conditions	Standard			Unit
		Farameter	Conditions	Min.	Тур.	Max.	Unit
_	Resolution		Vref = AVCC	-	-	10	Bits
-	Absolute	10-bit mode	$\phi$ AD = 10 MHz, Vref = AVCC = 5.0 V	-	-	±3	LSB
	accuracy	8-bit mode	$\phi$ AD = 10 MHz, Vref = AVCC = 5.0 V	-	-	±2	LSB
		10-bit mode	$\phi$ AD = 10 MHz, Vref = AVCC = 3.3 V	-	-	±5	LSB
	8	8-bit mode	$\phi$ AD = 10 MHz, Vref = AVCC = 3.3 V	-	_	±2	LSB
Rladder	Resistor ladder		Vref = AVCC	10	_	40	kΩ
tconv	Conversion time	10-bit mode	$\phi$ AD = 10 MHz, Vref = AVCC = 5.0 V	3.3	_	-	μS
		8-bit mode	$\phi$ AD = 10 MHz, Vref = AVCC = 5.0 V	2.8	_	-	μS
Vref	Reference voltag	e		2.7	_	AVcc	V
Via	Analog input volta	age <sup>(2)</sup>		0	-	AVcc	V
-	A/D operating	Without sample and hold		0.25	_	10	MHz
	clock frequency	With sample and hold		1	_	10	MHz

Table 5.36 A/D Converter Characteristics

NOTES:

1. AVcc = 2.7 to 5.5 V at  $T_{opr}$  = -40 to 85°C (J version) / -40 to 125°C (K version), unless otherwise specified.

2. When the analog input voltage is over the reference voltage, the A/D conversion result will be 3FFh in 10-bit mode and FFh in 8-bit mode.



Figure 5.20 Ports P0, P1, and P3 to P5 Timing Measurement Circuit

Cumhal	Parameter	Conditions		Linit		
Symbol		Conditions	Min.	Тур.	Max.	- Unit
-	Program/erase endurance <sup>(2)</sup>	R8C/26 Group	100 <sup>(3)</sup>	-	-	times
		R8C/27 Group	1,000 <sup>(3)</sup>	-	-	times
-	Byte program time		-	50	400	μS
-	Block erase time		-	0.4	9	S
td(SR-SUS)	Time delay from suspend request until		-	-	97 + CPU clock	μS
	suspend				× 6 cycles	
_	Interval from erase start/restart until following suspend request		650	-	_	μS
-	Interval from program start/restart until following suspend request		0	-	-	ns
-	Time from suspend until program/erase restart		-	_	3 + CPU clock × 4 cycles	μS
-	Program, erase voltage		2.7	_	5.5	V
-	Read voltage		2.7	-	5.5	V
_	Program, erase temperature		0	-	60	°C
-	Data hold time <sup>(7)</sup>	Ambient temperature = 55°C	20	-	_	year

NOTES: 1. Vcc = 2.7 to 5.5 V at  $T_{opr}$  = 0 to 60°C, unless otherwise specified.

2. Definition of programming/erasure endurance The programming and erasure endurance is defined on a per-block basis. If the programming and erasure endurance is n (n = 100 or 1,000), each block can be erased n times. For example, if 1,024 1-byte writes are performed to different addresses in block A, a 1 Kbyte block, and then the block is erased, the programming/erasure endurance still stands at one. However, the same address must not be programmed more than once per erase operation (overwriting prohibited).

3. Endurance to guarantee all electrical characteristics after program and erase. (1 to Min. value can be guaranteed). 4. In a system that executes multiple programming operations, the actual erasure count can be reduced by writing to sequential addresses in turn so that as much of the block as possible is used up before performing an erase operation. For example, when programming groups of 16 bytes, the effective number of rewrites can be minimized by programming up to 128 groups before erasing them all in one operation. It is also advisable to retain data on the erasure endurance of each block and limit

the number of erase operations to a certain number. 5. If an error occurs during block erase, attempt to execute the clear status register command, then execute the block erase

command at least three times until the erase error does not occur.

6. Customers desiring program/erase failure rate information should contact their Renesas technical support representative.

7. The data hold time includes time that the power supply is off or the clock is not supplied.

Symbol	Parameter	Conditions		Unit		
Cymbol		Conditions	Min.	Тур.	Max.	Unit
-	Program/erase endurance <sup>(2)</sup>		10,000 <sup>(3)</sup>	-	-	times
-	Byte program time (program/erase endurance ≤ 1,000 times)		-	50	400	μS
-	Byte program time (program/erase endurance > 1,000 times)		-	65	_	μS
-	Block erase time (program/erase endurance ≤ 1,000 times)		-	0.2	9	S
-	Block erase time (program/erase endurance > 1,000 times)		-	0.3	_	S
td(SR-SUS)	Time delay from suspend request until suspend		-	-	97 + CPU clock × 6 cycles	μS
-	Interval from erase start/restart until following suspend request		650	-	_	μS
-	Interval from program start/restart until following suspend request		0	-	_	ns
-	Time from suspend until program/erase restart		-	-	3 + CPU clock × 4 cycles	μS
-	Program, erase voltage		2.7	-	5.5	V
-	Read voltage		2.7	-	5.5	V
-	Program, erase temperature		-40	-	85 <sup>(8)</sup>	°C
-	Data hold time <sup>(9)</sup>	Ambient temperature = 55°C	20	-	-	year

Table 5.38	Flash Memory (Data flash Block A, Block B) Electrical Characteristics <sup>(4)</sup>
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NOTES: 1. Vcc = 2.7 to 5.5 V at Topr = -40 to 85°C (J version) / -40 to 125°C (K version), unless otherwise specified.

2. Definition of programming/erasure endurance

The programming and erasure endurance is defined on a per-block basis.

If the programming and erasure endurance is n (n = 10,000), each block can be erased n times. For example, if 1,024 1-byte writes are performed to different addresses in block A, a 1 Kbyte block, and then the block is erased, the programming/erasure endurance still stands at one.

However, the same address must not be programmed more than once per erase operation (overwriting prohibited).

3. Endurance to guarantee all electrical characteristics after program and erase. (1 to Min. value can be guaranteed).

- 4. Standard of block A and block B when program and erase endurance exceeds 1,000 times. Byte program time to 1,000 times is the same as that in program ROM.
- 5. In a system that executes multiple programming operations, the actual erasure count can be reduced by writing to sequential addresses in turn so that as much of the block as possible is used up before performing an erase operation. For example, when programming groups of 16 bytes, the effective number of rewrites can be minimized by programming up to 128 groups before erasing them all in one operation. In addition, averaging the erasure endurance between blocks A and B can further reduce the actual erasure endurance. It is also advisable to retain data on the erasure endurance of each block and limit the number of erase operations to a certain number.

6. If an error occurs during block erase, attempt to execute the clear status register command, then execute the block erase command at least three times until the erase error does not occur.

7. Customers desiring program/erase failure rate information should contact their Renesas technical support representative.

8. 125°C for K version.

9. The data hold time includes time that the power supply is off or the clock is not supplied.



Figure 5.21 Time delay until Suspend

#### Table 5.39 Voltage Detection 1 Circuit Electrical Characteristics

Symbol	Parameter	Condition		Unit		
Symbol	Falanetei	Condition	Min.	Тур.	Max.	Unit
Vdet1	Voltage detection level <sup>(2, 4)</sup>		2.70	2.85	3.0	V
td(Vdet1-A)	Voltage monitor 1 reset generation time <sup>(5)</sup>		-	40	200	μS
-	Voltage detection circuit self power consumption	VCA26 = 1, Vcc = 5.0 V	-	0.6	-	μΑ
td(E-A)	Waiting time until voltage detection circuit operation starts <sup>(3)</sup>		-	-	100	μS
Vccmin	MCU operating voltage minimum value		2.70	_	_	V

NOTES:

1. The measurement condition is Vcc = 2.7 to 5.5 V and Topr = -40 to 85°C (J version) / -40 to 125°C (K version).

2. Hold Vdet2 > Vdet1.

3. Necessary time until the voltage detection circuit operates when setting to 1 again after setting the VCA26 bit in the VCA2 register to 0.

4. This parameter shows the voltage detection level when the power supply drops.

- The voltage detection level when the power supply rises is higher than the voltage detection level when the power supply drops by approximately 0.1 V.
- 5. Time until the voltage monitor 1 reset is generated after the voltage passes Vdet1 when Vcc falls. When using the digital filter, its sampling time is added to td(Vdet1-A). When using the voltage monitor 1 reset, maintain this time until Vcc = 2.0 V after the voltage passes Vdet1 when the power supply falls.

#### Table 5.40 Voltage Detection 2 Circuit Electrical Characteristics

Symbol	Parameter	Condition		Unit		
Symbol	Falanetei	Condition	Min.	Тур.	Max.	Unit
Vdet2	Voltage detection level <sup>(2)</sup>		3.3	3.6	3.9	V
td(Vdet2-A)	Voltage monitor 2 reset/interrupt request generation time <sup>(3, 5)</sup>		-	40	200	μS
-	Voltage detection circuit self power consumption	VCA27 = 1, Vcc = 5.0 V	-	0.6	-	μA
td(E-A)	Waiting time until voltage detection circuit operation starts <sup>(4)</sup>		-	-	100	μS

NOTES:

1. The measurement condition is Vcc = 2.7 to 5.5 V and  $T_{opr} = -40$  to  $85^{\circ}C$  (J version) / -40 to  $125^{\circ}C$  (K version).

2. Hold Vdet2 > Vdet1.

3. Time until the voltage monitor 2 reset/interrupt request is generated after the voltage passes Vdet2.

- 4. Necessary time until the voltage detection circuit operates after setting to 1 again after setting the VCA27 bit in the VCA2 register to 0.
- 5. When using the digital filter, its sampling time is added to td(Vdet2-A). When using the voltage monitor 2 reset, maintain this time until Vcc = 2.0 V after the voltage passes Vdet2 when the power supply falls.

Symbol	Parameter	Condition		Unit		
Symbol	Faranieter	Condition	Min.	Тур.	Max.	Unit
Vpor1	Power-on reset valid voltage <sup>(4)</sup>		-	-	0.1	V
Vpor2	Power-on reset or voltage monitor 1 reset valid voltage		0	-	Vdet1	V
trth	External power Vcc rise gradient	$Vcc \le 3.6 V$	20(2)	-	-	mV/msec
		Vcc > 3.6 V	20 <sup>(2)</sup>	-	2,000	mV/msec

Table 5.41	Power-on Reset Circuit,	Voltage Monitor	1 Reset Electrical Characteristics <sup>(3)</sup>
		vontago mornitor	

NOTES:

- 1. The measurement condition is Topr = -40 to 85°C (J version) / -40 to 125°C (K version), unless otherwise specified.
- 2. This condition (the minimum value of external power Vcc rise gradient) does not apply if  $V_{Por2} \ge 1.0 V$ .
- 3. To use the power-on reset function, enable voltage monitor 1 reset by setting the LVD1ON bit in the OFS register to 0, the VW1C0 and VW1C6 bits in the VW1C register to 1 respectively, and the VCA26 bit in the VCA2 register to 1.
- 4. tw(por1) indicates the duration the external power Vcc must be held below the effective voltage (Vpor1) to enable a power on reset. When turning on the power for the first time, maintain tw(por1) for 30 s or more if  $-20^{\circ}C \le T_{opr} \le 125^{\circ}C$ , maintain tw(por1) for 3,000 s or more if  $-40^{\circ}C \le T_{opr} < -20^{\circ}C$ .



Figure 5.22 Reset Circuit Electrical Characteristics

Symbol	Parameter	Condition		Standard			
Symbol	Falameter	Condition	Min.	Тур.	Max.	Unit	
fOCO40M	High-speed on-chip oscillator frequency temperature - supply voltage dependence	$ \begin{array}{l} \mbox{Vcc} = 4.75 \mbox{ to } 5.25 \mbox{ V} \\ \mbox{0}^{\circ}\mbox{C} \leq \mbox{Topr} \leq 60^{\circ}\mbox{C}^{(2)} \\ \end{array} $	39.2	40	40.8	MHz	
		$\label{eq:Vcc} \begin{array}{l} \mbox{Vcc} = 3.0 \mbox{ to } 5.5 \mbox{ V} \\ \mbox{-}20^{\circ}\mbox{C} \leq \mbox{Topr} \leq 85^{\circ}\mbox{C}^{(2)} \end{array}$	38.8	40	41.2	MHz	
		$\label{eq:Vcc} \begin{array}{l} \mbox{Vcc} = 3.0 \mbox{ to } 5.5 \mbox{ V} \\ \mbox{-40}^{\circ}\mbox{C} \leq \mbox{Topr} \leq 85^{\circ}\mbox{C}^{(2)} \end{array}$	38.4	40	41.6	MHz	
		Vcc = 3.0  to  5.5  V -40°C ≤ Topr ≤ 125°C <sup>(2)</sup>	38	40	42	MHz	
		$V_{CC} = 2.7 \text{ to } 5.5 \text{ V}$ -40°C ≤ Topr ≤ 125°C <sup>(2)</sup>	37.6	40	42.4	MHz	
-	Value in FRA1 register after reset		08h	-	F7h	_	
-	Oscillation frequency adjustment unit of high- speed on-chip oscillator	Adjust FRA1 register (value after reset) to -1	-	+0.3	-	MHz	
-	Oscillation stability time		-	10	100	μS	
-	Self power consumption at oscillation	Vcc = 5.0 V, Topr = 25°C	-	400	=	μA	

Table 5.42 High-speed On-Chip Oscillator Circuit Electrical Characteristics

NOTES:

1. Vcc = 2.7 to 5.5 V, Topr = -40 to 85°C (J version) / -40 to 125°C (K version), unless otherwise specified.

2. These standard values show when the FRA1 register value after reset is assumed.

#### Table 5.43 Low-speed On-Chip Oscillator Circuit Electrical Characteristics

Symbol	Parameter	Condition		Unit		
Symbol	Falameter	Condition	Min.	Тур.	Max.	Unit
fOCO-S	Low-speed on-chip oscillator frequency		40	125	250	kHz
-	Oscillation stability time		-	10	100	μS
-	Self power consumption at oscillation	VCC = 5.0 V, Topr = $25^{\circ}C$	-	15	-	μΑ

NOTE:

1. Vcc = 2.7 to 5.5 V, Topr = -40 to 85°C (J version) / -40 to 125°C (K version), unless otherwise specified.

#### Table 5.44 Power Supply Circuit Timing Characteristics

Symbol	Parameter	Condition		Unit		
Symbol	Falanetei	Condition	Min.	Тур.	Max.	Offic
td(P-R)	Time for internal power supply stabilization during power-on <sup>(2)</sup>		1	-	2000	μS
td(R-S)	STOP exit time <sup>(3)</sup>		-	-	150	μS

NOTES:

1. The measurement condition is Vcc = 2.7 to 5.5 V and Topr =  $25^{\circ}$ C.

2. Waiting time until the internal power supply generation circuit stabilizes during power-on.

3. Time until system clock supply starts after the interrupt is acknowledged to exit stop mode.

Cumhal	Deremete		Conditions		Stand	ard	Unit
Symbol	Paramete	er	Conditions	Min.	Тур.	Max.	
tsucyc	SSCK clock cycle tim	e		4	_	-	tCYC <sup>(2)</sup>
tнı	SSCK clock "H" width	1		0.4	_	0.6	tsucyc
tLO	SSCK clock "L" width			0.4	I	0.6	tsucyc
trise	SSCK clock rising	Master		-	-	1	tCYC <sup>(2)</sup>
	time	Slave		-	-	1	μs
tFALL	SSCK clock falling	Master		-	-	1	tCYC <sup>(2)</sup>
	time	Slave		-	I	1	μs
ts∪	SSO, SSI data input s	setup time		100	-	-	ns
tн	SSO, SSI data input I	nold time		1	-	-	tCYC <sup>(2)</sup>
<b>t</b> LEAD	SCS setup time	Slave		1tcyc + 50	-	-	ns
tlag	SCS hold time	Slave		1tcyc + 50	-	-	ns
top	SSO, SSI data output	delay time		-	-	1	tCYC <sup>(2)</sup>
tsa	SSI slave access time	e		-	-	1.5tcyc + 100	ns
tor	SSI slave out open tir	ne		-	_	1.5tcyc + 100	ns

#### Table 5.45 Timing Requirements of Clock Synchronous Serial I/O with Chip Select<sup>(1)</sup>

NOTES:

1. Vcc = 2.7 to 5.5 V, Vss = 0 V at T<sub>opr</sub> = -40 to 85°C (J version) / -40 to 125°C (K version), unless otherwise specified. 2.  $1t_{CYC} = 1/f1(s)$ 







Figure 5.24 I/O Timing of Clock Synchronous Serial I/O with Chip Select (Slave)



Figure 5.25 I/O Timing of Clock Synchronous Serial I/O with Chip Select (Clock Synchronous Communication Mode)

Table 5.46 Ti	iming Requirements	of I <sup>2</sup> C bus Interface <sup>(1)</sup>
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Symbol	Parameter	Condition	Sta	Unit		
Symbol	Parameter	Condition	Min.	Тур.	Max.	
tSCL	SCL input cycle time		12tcyc + 600 <sup>(2)</sup>	-	-	ns
<b>t</b> SCLH	SCL input "H" width		3tcyc + 300 <sup>(2)</sup>	-	-	ns
tSCLL	SCL input "L" width		5tcyc + 500 <sup>(2)</sup>	-	_	ns
tsf	SCL, SDA input fall time		-	-	300	ns
tSP	SCL, SDA input spike pulse rejection time		-	-	1tcyc <sup>(2)</sup>	ns
tbuf	SDA input bus-free time		5tcyc <sup>(2)</sup>	-	-	ns
<b>t</b> STAH	Start condition input hold time		3tcyc <sup>(2)</sup>	-	-	ns
<b>t</b> STAS	Retransmit start condition input setup time		3tCYC <sup>(2)</sup>	-	-	ns
<b>t</b> STOP	Stop condition input setup time		3tcyc <sup>(2)</sup>	-	-	ns
tsdas	Data input setup time		1tcyc + 20 <sup>(2)</sup>	-	-	ns
<b>t</b> SDAH	Data input hold time		0	-	-	ns

NOTES:

1. Vcc = 2.7 to 5.5 V, Vss = 0 V at Topr = -40 to  $85^{\circ}$ C (J version) / -40 to  $125^{\circ}$ C (K version), unless otherwise specified.

2. 1tcyc = 1/f1(s)



Figure 5.26 I/O Timing of I<sup>2</sup>C bus Interface

Symbol	Do	rameter	Conditio	2	Si	tandard		Unit
Symbol	Fdi	ameter	Condition		Min.	Тур.	Max.	Unit
Vон	Output "H" voltage	Except XOUT	Iон = -5 mA		Vcc - 2.0	I	Vcc	V
			Іон = -200 μА		Vcc - 0.3	I	Vcc	V
		XOUT	Drive capacity HIGH	Iон = -1 mA	Vcc - 2.0	-	Vcc	V
			Drive capacity LOW	Іон = -500 μА	Vcc - 2.0	I	Vcc	V
Vol	Output "L" voltage	Except XOUT	IOL = 5 mA	•	-	-	2.0	V
			Ιοι = 200 μΑ		-	-	0.45	V
		XOUT	Drive capacity HIGH	IoL = 1 mA	-	-	2.0	V
			Drive capacity LOW	Iol = 500 μA	-	I	2.0	V
Vt+-Vt-	Hysteresis	INT0, INT1, INT3, KI0, KI1, KI2, KI3, TRAIO, RXD0, RXD1, CLK0, CLK1, SSI, SCL, SDA, SSO			0.1	0.5	_	V
		RESET			0.1	1.0	-	V
Ін	Input "H" current		VI = 5 V, Vcc = 5V		-	-	5.0	μA
lı∟	Input "L" current		VI = 0 V, $Vcc = 5V$		-	-	-5.0	μA
Rpullup	Pull-up resistance		VI = 0 V, Vcc = 5V		30	50	167	kΩ
RfXIN	Feedback resistance	XIN			-	1.0	-	MΩ
Vram	RAM hold voltage	•	During stop mode		2.0	_	—	V

### Table 5.47 Electrical Characteristics (1) [Vcc = 5 V]

NOTE:

1. Vcc = 4.2 to 5.5 V at Topr = -40 to 85°C (J version) / -40 to 125°C (K version), f(XIN) = 20 MHz, unless otherwise specified.

# Table 5.48Electrical Characteristics (2) [Vcc = 5 V]<br/>(Topr = -40 to 85°C (J version) / -40 to 125°C (K version), unless otherwise specified.)

				01		
Parameter		Condition	Min.		Max.	Unit
Power supply current (Vcc = 3.3 to 5.5 V) Single-chip mode,	High-speed clock mode	XIN = 20 MHz (square wave) High-speed on-chip oscillator off Low-speed on-chip oscillator on = 125 kHz No division	_	10	17	mA
output pins are open, other pins are Vss		XIN = 16 MHz (square wave) High-speed on-chip oscillator off Low-speed on-chip oscillator on = 125 kHz No division	_	9	15	mA
		XIN = 10 MHz (square wave) High-speed on-chip oscillator off Low-speed on-chip oscillator on = 125 kHz No division	_	6	l	mA
		XIN = 20 MHz (square wave) High-speed on-chip oscillator off Low-speed on-chip oscillator on = 125 kHz Divide-by-8	_	5	-	mA
		XIN = 16 MHz (square wave) High-speed on-chip oscillator off Low-speed on-chip oscillator on = 125 kHz Divide-by-8	_	4	_	mA
		XIN = 10 MHz (square wave) High-speed on-chip oscillator off Low-speed on-chip oscillator on = 125 kHz Divide-by-8		2.5	l	mA
	High-speed on-chip oscillator	XIN clock off High-speed on-chip oscillator on fOCO = 20 MHz (J version) Low-speed on-chip oscillator on = 125 kHz No division	-	10	15	mA
	mode	XIN clock off High-speed on-chip oscillator on fOCO = 20 MHz (J version) Low-speed on-chip oscillator on = 125 kHz Divide-by-8	_	4	_	mA
		XIN clock off High-speed on-chip oscillator on fOCO = 10 MHz Low-speed on-chip oscillator on = 125 kHz No division	_	5.5	10	mA
		XIN clock off High-speed on-chip oscillator on fOCO = 10 MHz Low-speed on-chip oscillator on = 125 kHz Divide-by-8	_	2.5	_	mA
	Low-speed on-chip oscillator mode	XIN clock off High-speed on-chip oscillator off Low-speed on-chip oscillator on = 125 kHz Divide-by-8, FMR47 = 1		130	300	μA
	Wait mode	XIN clock off High-speed on-chip oscillator off Low-speed on-chip oscillator on = 125 kHz While a WAIT instruction is executed Peripheral clock operation VCA27 = VCA26 = VCA25 = 0 VCA20 = 1		25	75	μA
		XIN clock off High-speed on-chip oscillator off Low-speed on-chip oscillator on = 125 kHz While a WAIT instruction is executed Peripheral clock off VCA27 = VCA26 = VCA25 = 0 VCA20 = 1	_	23	60	μA
	Stop mode	XIN clock off, Topr = $25^{\circ}$ C High-speed on-chip oscillator off Low-speed on-chip oscillator off CM10 = 1 Peripheral clock off VCA27 = VCA26 = VCA25 = 0	_	0.8	3.0	μA
		XIN clock off, Topr = $85^{\circ}$ C High-speed on-chip oscillator off Low-speed on-chip oscillator off CM10 = 1 Peripheral clock off VCA27 = VCA26 = VCA25 = 0	_	1.2	_	μA
		XIN clock off, Topr = 125°C High-speed on-chip oscillator off Low-speed on-chip oscillator off CM10 = 1 Peripheral clock off	_	4.0	_	μA
	Power supply current (Vcc = 3.3 to 5.5 V) Single-chip mode, output pins are open,	Power supply current (Vcc = 3.3 to 5.5 V) Single-chip mode, output pins are open, other pins are Vss       High-speed         Image: High-speed on-chip oscillator mode       High-speed         Image: High-speed on-chip oscillator mode       Low-speed         Image: Wait mode       Wait mode	Power supply current (Vcc = 3.3 to 5.5 V) Single-chip mode, output pins are open, other pins are Vss         XIN = 20 MHz (square wave) High-speed on-chip oscillator off Low-speed on-chip oscillator off High-speed on-chip oscillator off Low-speed on-chip oscillator off Low-speed on-chip oscillator on e125 kHz Ni clock off High-speed on-chip oscillator on e125 kHz Ni clock off High-speed on-chip oscillator on e125 kHz Ni clock off High-speed on-chip oscillator off = 25 kHz Ni clock off High-speed on-chip oscillator off Low-speed on-chip oscillator off CA27 = VCA28	Parameter         Condition         Min.           Power supply current (VCc = 3.3 to 5.5 V) Single-chip mode, other pins are Vss         High-speed lock mode         XIN = 20 MHz (square wave) High-speed on-chip oscillator of Low-speed on-chip oscillator of Log Low Low-speed on-chip oscillator of Low speed On-chip oscillator of Log Low Low-speed on-chip oscillator of Low-speed on-chip oscillator o	Parameter         Condition         Min.         Typ.           Power supply current (VCc a 3, 31 6 5 V) Single-thip mode, output prins are vss         KIN = 20 MHz (square wave) High-speed on-chip occiliator of Low-speed on-chip occiliator of LoS Hz Divide-by-8         -         2.5           XIN tock off High-speed on-chip occiliator on 1020 = 20 MHz (J version occiliator nocle         -         4         -         2.5           XIN tock off High-speed on-chip osciliator on 1020 = 10 MHz Divide-by-8         -         2.5         -         -         2.5           XIN tock off High-speed on-chip osciliator on 125 KHz Divide-by-8         -         2.5         -         -         2.5           XIN tock off High-speed on-chip osciliator on 125 KHz Divide-by-8         -	Power supply current (Vcc = 3.3 to 5.5 V) Single-chip model, output pins are open, other pins are Vss         XIN = 20 MHz (square wave) High-speed on-the scalinot off Low-speed on-the scalinot off Low-speed on-the Low-speed on-the scalinot off Low-speed on-the scalinot off

#### Timing Requirements (Unless Otherwise Specified: Vcc = 5 V, Vss = 0 V at Topr = 25°C) [Vcc = 5 V]

#### Table 5.49XIN Input

Symbol	Symbol Parameter -		dard	Unit
Symbol			Max.	Unit
tc(XIN)	XIN input cycle time	50	-	ns
twh(xin)	XIN input "H" width	25	-	ns
twl(XIN)	XIN input "L" width	25	-	ns



Figure 5.27 XIN Input Timing Diagram when Vcc = 5 V

#### Table 5.50 TRAIO Input

Symbol	Parameter	Stan	Unit	
Symbol			Max.	Onit
tc(TRAIO)	TRAIO input cycle time	100	-	ns
twh(traio)	TRAIO input "H" width	40	-	ns
twl(traio)	TRAIO input "L" width	40	-	ns



Figure 5.28 TRAIO Input Timing Diagram when Vcc = 5 V

Table 5.51 Serial Interface
-----------------------------

Symbol	Parameter		Standard		
	Faianetei	Min.	Max.	Unit	
tc(CK)	CLKi input cycle time	200	-	ns	
tw(CKH)	CLKi input "H" width	100	-	ns	
tW(CKL)	CLKi input "L" width	100	-	ns	
td(C-Q)	TXDi output delay time	-	50	ns	
th(C-Q)	TXDi hold time	-	ns		
tsu(D-C)	RXDi input setup time	50	-	ns	
th(C-D)	RXDi input hold time 90 -				

i = 0 or 1





#### Table 5.52 External Interrupt INTi (i = 0, 1, 3) Input

Symbol	Parameter		Standard		
Symbol			Max.	Unit	
tw(INH)	INTi input "H" width	250 <sup>(1)</sup>	-	ns	
tw(INL)	INTi input "L" width         250 <sup>(2)</sup> -				

NOTES:

1. When selecting the digital filter by the INTi input filter select bit, use an INTi input HIGH width of either (1/digital filter clock frequency × 3) or the minimum value of standard, whichever is greater.

2. When selecting the digital filter by the INTi input filter select bit, use an INTi input LOW width of either (1/digital filter clock frequency × 3) or the minimum value of standard, whichever is greater.



Figure 5.30 External Interrupt INTi Input Timing Diagram when Vcc = 5 V

Symbol	Dorr	ameter	Cond	ition	S	tandard		Unit	
Symbol	Fdia	ameter	Cond		Min. Typ. Max.			01111	
Vон	Output "H" voltage	Except XOUT	Іон = -1 mA		Vcc - 0.5	-	Vcc	V	
		XOUT	Drive capacity HIGH	Iон = -0.1 mA	Vcc - 0.5	-	Vcc	V	
			Drive capacity LOW	Іон = -50 μА	Vcc - 0.5	-	Vcc	V	
Vol	Output "L" voltage	Except XOUT	lo∟ = 1 mA		-	-	0.5	V	
	XOUT	Drive capacity HIGH	IoL = 0.1 mA	-	-	0.5	V		
			Drive capacity LOW	Io∟ = 50 μA	-	-	0.5	V	
VT+-VT-	Hysteresis	INT0, INT1, INT3, KI0, KI1, KI2, KI3, TRAIO, RXD0, RXD1, CLK0,CLK1, SSI, SCL, SDA, SSO			0.1	0.3	_	V	
		RESET			0.1	0.4	-	V	
Ін	Input "H" current		VI = 3 V, Vcc = 3	V	_	-	4.0	μA	
lı∟	Input "L" current		VI = 0 V, Vcc = 3	V	_	-	-4.0	μA	
Rpullup	Pull-up resistance		VI = 0 V, Vcc = 3	V	66	160	500	kΩ	
Rfxin	Feedback resistance	XIN			-	3.0	-	MΩ	
VRAM	RAM hold voltage	•	During stop mode	e	2.0	-	-	V	

### Table 5.53 Electrical Characteristics (3) [Vcc = 3 V]

NOTE:

1. Vcc = 2.7 to 3.3 V at Topr = -40 to 85°C (J version) / -40 to 125°C (K version), f(XIN) = 10 MHz, unless otherwise specified.



# Table 5.54Electrical Characteristics (4) [Vcc = 3 V]<br/>(Topr = -40 to 85°C (J version) / -40 to 125°C (K version), unless otherwise specified.)

Symbol	Parameter		Condition		Standar	d	Unit
Symbol				Min.	Тур.	Max.	Unit
Icc	Power supply current (Vcc = 2.7 to 3.3 V) Single-chip mode, output pins are open,	High-speed clock mode	XIN = 10 MHz (square wave) High-speed on-chip oscillator off Low-speed on-chip oscillator on = 125 kHz No division	_	6	_	mA
	other pins are Vss		XIN = 10 MHz (square wave) High-speed on-chip oscillator off Low-speed on-chip oscillator on = 125 kHz Divide-by-8	_	2	-	mA
		High-speed on-chip oscillator mode	XIN clock off High-speed on-chip oscillator on fOCO = 10 MHz Low-speed on-chip oscillator on = 125 kHz No division	_	5	9	mA
			XIN clock off High-speed on-chip oscillator on fOCO = 10 MHz Low-speed on-chip oscillator on = 125 kHz Divide-by-8	_	2	_	mA
		Low-speed on-chip oscillator mode	XIN clock off High-speed on-chip oscillator off Low-speed on-chip oscillator on = 125 kHz Divide-by-8, FMR47 = 1	-	130	300	μA
		Wait mode	XIN clock off High-speed on-chip oscillator off Low-speed on-chip oscillator on = 125 kHz While a WAIT instruction is executed Peripheral clock operation VCA27 = VCA26 = VCA25 = 0 VCA20 = 1	_	25	70	μΑ
			XIN clock off High-speed on-chip oscillator off Low-speed on-chip oscillator on = 125 kHz While a WAIT instruction is executed Peripheral clock off VCA27 = VCA26 = VCA25 = 0 VCA20 = 1	-	23	55	μΑ
		Stop mode	XIN clock off, $T_{opr} = 25^{\circ}C$ High-speed on-chip oscillator off Low-speed on-chip oscillator off CM10 = 1 Peripheral clock off VCA27 = VCA26 = VCA25 = 0	_	0.7	3.0	μA
			XIN clock off, $T_{opr} = 85^{\circ}C$ High-speed on-chip oscillator off Low-speed on-chip oscillator off CM10 = 1 Peripheral clock off VCA27 = VCA26 = VCA25 = 0	_	1.1	_	μA
			XIN clock off, Topr = 125°C High-speed on-chip oscillator off Low-speed on-chip oscillator off CM10 = 1 Peripheral clock off VCA27 = VCA26 = VCA25 = 0	_	3.8	_	μA

#### Timing requirements (Unless Otherwise Specified: Vcc = 3 V, Vss = 0 V at Topr = 25°C) [Vcc = 3 V]

#### Table 5.55 XIN Input

Symbol	Parameter		Standard		
Symbol			Max.	Unit	
tc(XIN)	XIN input cycle time	100	-	ns	
twh(xin)	XIN input "H" width 40 -				
twl(XIN)	XIN input "L" width 40 –				



Figure 5.31 XIN Input Timing Diagram when Vcc = 3 V

#### Table 5.56 TRAIO Input

Symbol	Parameter		Standard		
Symbol			Max.	Unit	
tc(TRAIO)	TRAIO input cycle time	300	-	ns	
twh(traio)	TRAIO input "H" width	-	ns		
twl(traio)	TRAIO input "L" width 120 -				



Figure 5.32 TRAIO Input Timing Diagram when Vcc = 3 V

Symbol	Parameter		Standard		
	Faianelei	Min.	Max.	Unit	
tc(CK)	CLKi input cycle time	300	-	ns	
tw(CKH)	CLKi input "H" width	150	-	ns	
tW(CKL)	CLKi Input "L" width	150	-	ns	
td(C-Q)	TXDi output delay time	-	80	ns	
th(C-Q)	TXDi hold time	-	ns		
tsu(D-C)	RXDi input setup time	70	-	ns	
th(C-D)	RXDi input hold time 90 –				

i = 0 or 1





#### Table 5.58 External Interrupt INTi (i = 0, 1, 3) Input

Symbol	Parameter		Standard		
Symbol			Max.	Unit	
tw(INH)	INTi input "H" width	380(1)	-	ns	
tw(INL)	INTi input "L" width         380 <sup>(2)</sup> -				

NOTES:

1. When selecting the digital filter by the INTi input filter select bit, use an INTi input HIGH width of either (1/digital filter clock frequency × 3) or the minimum value of standard, whichever is greater.

2. When selecting the digital filter by the INTi input filter select bit, use an INTi input LOW width of either (1/digital filter clock frequency x 3) or the minimum value of standard, whichever is greater.



Figure 5.34 External Interrupt INTi Input Timing Diagram when Vcc = 3 V

## **Package Dimensions**

Diagrams showing the latest package dimensions and mounting information are available in the "Packages" section of the Renesas Technology website.



## **REVISION HISTORY**

# R8C/26 Group, R8C/27 Group Datasheet

D	Data		Description
Rev.	Date	Page	Summary
0.10	Nov 14, 2005	_	First edition issued
0.20	Feb 06, 2006	2, 3	Table 1.1 Functions and Specifications for R8C/26Group and Table 1.2Functions and Specifications for R8C/27 Group;Minimum instruction execution time and Supply voltage revised
		9	Table 1.6 Pin Name Information by Pin Number; "XOUT" $\rightarrow$ "XOUT/XCOUT" and "XIN" $\rightarrow$ "XIN/XCIN" revised
		18	Table 4.4 SFR Information (4); 00FEh: "DRR" $\rightarrow$ "P1DRR" revised
		19	<ul> <li>Table 4.5 SFR Information (5);</li> <li>-0119h: "Timer RE Minute Data Register / Compare Register" →     "Timer RE Minute Data Register / Compare Data Register"</li> <li>-011Ah: "Timer RE Time Data Register" →     "Timer RE Hour Data Register"</li> <li>-011Bh: "Timer RE Day Data Register" →     "Timer RE Day of Week Data Register" revised</li> </ul>
		22 to 45	5. Electrical Characteristics added
1.00	Nov 08, 2006	All pages	"Preliminary" deleted
		2	Table 1.1 revised
		3	Table 1.2 revised
		4	Figure 1.1 revised
		5	Table 1.3 revised
		6	Table 1.4 revised
		7	Figure 1.4 revised
		9	Table 1.6 revised
		15	Table 4.1; • 001Ch: "00h" $\rightarrow$ "00h, 1000000b" revised • 000Fh: "000XXXXXb" $\rightarrow$ "00X11111b" revised • 0029h: "High-Speed On-Chip Oscillator Control Register 4, FRA4, When shipping" added • 002Bh: "High-Speed On-Chip Oscillator Control Register 6, FRA6, When shipping" added • 0032h: "00h, 0100000b" $\rightarrow$ "00h, 0010000b" revised • 0038h: "00001000b, 01001001b" $\rightarrow$ "0000X000b, 0100X001b" revised • NOTE3 and 4 revised; NOTE6 added
		18	Table 4.4; • 00E0h, 00E1h, 00E5h, 00E8h, 00E9h: "XXh" → "00h" revised • 00FDh: "XX00000000b" → "00h" revised
		22	Table 5.2 revised
		23	Figure 5.1 title revised
		24	Table 5.4 revised
		25	Table 5.5 revised
		26	Figure 5.2 title revised and Table 5.7 NOTE4 added

## **REVISION HISTORY**

## R8C/26 Group, R8C/27 Group Datasheet

Davi	Dete		Description
Rev.	Date	Page	Summary
1.00	Nov 08, 2006	27	Table 5.9, Figure 5.3 revised and Table 5.10 deleted
		28	Table 5.10, Table 5.11 revised
		34	Table 5.15 revised
		35	Table 5.16 revised
		36	Table 5.17 revised
		39	Table 5.22 revised
		40	Table 5.23 revised
		44	Table 5.29 revised
		47	Package Dimensions; "Diagrams showing the latestwebsite." added
1.10	Nov 29, 2006	All pages	"J, K version" added
		1	1 "J and K versions are under developmentnotice." added 1.1 revised
		2	Table 1.1 revised
		3	Table 1.2 revised
		4	Figure 1.1 NOTE3 added
		5	Table 1.3, Figure 1.2 revised
		6	Table 1.4, Figure 1.3 revised
		7	Figure 1.4 NOTE3 added
		8	Table 1.5 revised
		9	Table 1.6 NOTE2 added
		13	Figure 3.1 revised
		14	Figure 3.2 revised
		15	Table 4.1; "0000h to 003Fh" → "0000h to 002Fh" revised • NOTE3 added
		16	<ul> <li>Table 4.2; "0040h to 007Fh" → "0030h to 007Fh" revised</li> <li>0032h, 0036h: "After reset" is revised</li> <li>0038h: NOTE revised</li> <li>NOTES 2, 5, 6 revised and NOTE 7, 8 added</li> </ul>
		19	Table 4.5 NOTE2 added
		28	Table 5.10 revised
		48 to 66	5.2 J, K Version added
1.20	Jan 17, 2007	18	Table 4.4 NOTE2 added
1.30	May 25, 2007	2	Table 1.1 revised
		3	Table 1.2 revised
		5	Table 1.3 revised
		6	Figure 1.2 revised
		7	Table 1.4 revised
		8	Figure 1.3 revised
		9	Figure 1.4 NOTE4 added
		15	Figure 3.1 part number revised

## **REVISION HISTORY**

## R8C/26 Group, R8C/27 Group Datasheet

Rev.	Date	Description	
		Page	Summary
1.30	May 25, 2007	16	Figure 3.2 part number revised
		30	Table 5.10 revised
		53	Table 5.39 NOTE4 added
		55	Table 5.42 revised
1.40a	Jun 14, 2007	5, 7	Table 1.3 and Table 1.4 revised
2.00	Mar 01, 2008	1, 49	1.1, 5.2 "J and K versions are" deleted
		5, 7	Table 1.3, Table 1.4 revised
		11	Table 1.6 NOTE3 added
		15, 16	Figure 3.1, Figure 3.2; "Expanded area" deleted
		17	Table 4.1 "002Ch" added
		18	Table 4.2 "0036h"; J, K version "0100X000b" → "0100X001b"
		24, 49	Table 5.2, Table 5.35; NOTE2 revised
		30	Table 5.10 revised, NOTE4 added
2.10	Sep 26, 2008	_	"RENESAS TECHNICAL UP DATE" reflected: TN-16C-A172A/E
		26, 51	Table 5.4, Table 5.37 NOTE2, NOTE4 revised
		27, 52	Table 5.5, Table 5.38 NOTE2, NOTE5 revised
		53	Table 5.39 Parameter: Voltage monitor 1 reset generation time added NOTE5 added
			Table 5.40 revised
		54	Table 5.41 revised Figure 5.22 revised

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